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## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Changes from Revision * (October 2022) to Revision A (March 2023)                                         | Page |
|-----------------------------------------------------------------------------------------------------------|------|
| • Corrected  9-59 ..... | 37   |

## 5 Device Comparison Table

| Device Number | Output Current | Input Voltage | Operating Temperature Range | Switching Frequency                 | PWM Mode                              | V <sub>O</sub> Adjust                          |  |  |  |
|---------------|----------------|---------------|-----------------------------|-------------------------------------|---------------------------------------|------------------------------------------------|--|--|--|
| TPS62993-Q1   | 0 A – 3 A      | 3 V – 10 V    | –40°C to 165°C              | Selectable 1-MHz or 2.5-MHz options | Selectable auto PFM/PWM or forced PWM | Externally programmable or 16 internal options |  |  |  |
| TPS62992-Q1   | 0 A – 2 A      |               |                             |                                     |                                       |                                                |  |  |  |
| TPS62903-Q1   | 0 A – 3 A      | 3 V – 18 V    | –40°C to 165°C              | Selectable 1-MHz or 2.5-MHz options | Selectable auto PFM/PWM or forced PWM | Externally programmable or 16 internal options |  |  |  |
| TPS62902-Q1   | 0 A – 2 A      |               |                             |                                     |                                       |                                                |  |  |  |
| TPS62901-Q1   | 0 A – 1 A      |               |                             |                                     |                                       |                                                |  |  |  |
| TPS62903      | 0 A – 0.3 A    | 3 V – 18 V    | –40°C to 125°C              | Selectable 1-MHz or 2.5-MHz options | Selectable auto PFM/PWM or forced PWM | Externally programmable or 16 internal options |  |  |  |
| TPS62902      | 0 A – 2 A      |               |                             |                                     |                                       |                                                |  |  |  |
| TPS62901      | 0 A – 1 A      |               | –55°C to 165°C              |                                     |                                       |                                                |  |  |  |
| TPS62903E     | 0 A – 3 A      |               |                             |                                     |                                       |                                                |  |  |  |

## 6 Pin Configuration and Functions

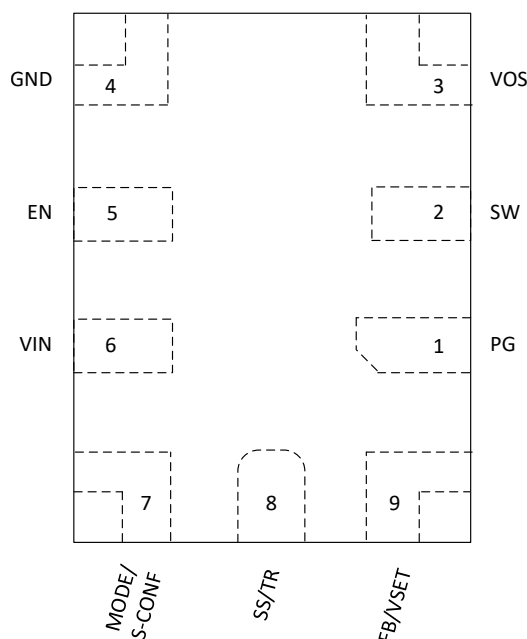


图 6-1. 9-Pin RYT VQFN Package (Top View, Device Pins Face Down)

表 6-1. Pin Functions

| Pin             |        | Type <sup>(1)</sup> | Description                                                                                                                                                                                                                                                                                                    |
|-----------------|--------|---------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Name            | Number |                     |                                                                                                                                                                                                                                                                                                                |
| PG              | 1      | O                   | Open-drain power-good output. High = $V_{OUT}$ is ready. Low = $V_{OUT}$ is below nominal regulation. This pin requires a pullup resistor.                                                                                                                                                                     |
| SW              | 2      | —                   | Switch pin of the converter and is connected to the internal power switches. Connect the inductor between SW and the output capacitor.                                                                                                                                                                         |
| VOS             | 3      | I                   | Output voltage sense pin. Connect directly to the positive pin of the output capacitor.                                                                                                                                                                                                                        |
| GND             | 4      | —                   | Ground pin. This pin must be connected directly to the common ground plane.                                                                                                                                                                                                                                    |
| EN              | 5      | I                   | Enable input pin. Connect to logic low to disable the device. Pull high to enable the device. Do not leave this pin unconnected.                                                                                                                                                                               |
| VIN             | 6      | I                   | Power supply input pin. Ensure the input capacitor is connected as close as possible between the VIN and GND pins.                                                                                                                                                                                             |
| MODE/<br>S-CONF | 7      | I                   | Device mode selection (auto PFM/PWM or forced PWM operation) and SmartConfig pin. Connect high, low, or to a resistor to configure the device according to 表 8-1. Do not leave this pin unconnected.                                                                                                           |
| SS/TR           | 8      | I                   | Soft start and tracking pin. An external capacitor connected from this pin to GND defines the rise time for the internal reference voltage. The pin can also be used as an input for tracking and sequencing. The pin can be left floating for the fastest ramp-up time.                                       |
| FB/VSET         | 9      | I                   | Depends on device configuration (see セクション 8.3.1.) <ul style="list-style-type: none"> <li>FB: Voltage feedback input. Connect a resistive output voltage divider to this pin.</li> <li>VSET: Output voltage setting pin. Connect a resistor to GND to choose the output voltage according to 表 8-2.</li> </ul> |

(1) O = output, I = input

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)<sup>(1)</sup>

|                        |                                        | MIN  | MAX                   | UNIT |
|------------------------|----------------------------------------|------|-----------------------|------|
| Voltage <sup>(2)</sup> | VIN, EN, PG, MODE/S-CONF               | −0.3 | 12                    | V    |
| Voltage <sup>(2)</sup> | SW <sup>(3)</sup>                      | −0.3 | V <sub>IN</sub> + 0.3 | V    |
| Voltage <sup>(2)</sup> | SW (AC, less than 10ns) <sup>(3)</sup> | −3.0 | 17                    | V    |
| Voltage <sup>(2)</sup> | FB/VSET, SS/TR, VOS                    | −0.3 | 6                     | V    |
| T <sub>J</sub>         | Junction temperature                   | −55  | 165                   | °C   |
| T <sub>stg</sub>       | Storage temperature                    | −65  | 165                   | °C   |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values are with respect to network ground terminal.
- (3) While switching.

### 7.2 ESD Ratings

|                    |                         |                                                                                                  | VALUE                                | UNIT |
|--------------------|-------------------------|--------------------------------------------------------------------------------------------------|--------------------------------------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per AEC-Q100-002 HBM ESD Classification Level 2, all pins <sup>(1)</sup> | ±2000                                | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | Charged device model (CDM), per AEC-Q100-011 CDM ESD Classification level C4B.                   | All pins<br>±500                     | V    |
|                    |                         |                                                                                                  | Corner pins (3, 4, 7, and 9)<br>±750 |      |

- (1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 7.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted)

|                      |                                                                | MIN | NOM | MAX                | UNIT |
|----------------------|----------------------------------------------------------------|-----|-----|--------------------|------|
| V <sub>I</sub>       | Input voltage range                                            | 3.0 |     | 10                 | V    |
| V <sub>O</sub>       | Output voltage range                                           | 0.4 |     | 5.5                | V    |
| C <sub>I</sub>       | Effective input capacitance                                    | 3   | 10  |                    | μF   |
| C <sub>O</sub>       | Effective output capacitance (2.5MHz selection) <sup>(1)</sup> | 10  | 22  | 100 <sup>(1)</sup> | μF   |
| C <sub>O</sub>       | Effective output capacitance (1MHz selection) <sup>(1)</sup>   | 10  | 22  | 100 <sup>(1)</sup> | μF   |
| L                    | Output inductance <sup>(2)</sup>                               | 1   | 2.2 | 4.7 <sup>(3)</sup> | μH   |
| I <sub>OUT</sub>     | Output current                                                 | 0   |     | 3                  | A    |
| I <sub>SINK_PG</sub> | Sink current at PG-Pin                                         |     |     | 1                  | mA   |
| T <sub>J</sub>       | Junction temperature <sup>(4)</sup>                            | −40 |     | 165                | °C   |

- (1) This is for capacitors directly at the output of the device. More capacitance is allowed if there is a series resistance associated to the capacitor.
- (2) Nominal inductance value.
- (3) Larger values of inductance may be used to reduce the ripple current, but they may have a negative impact on efficiency and the overall transient response.
- (4) Operating lifetime is derated at junction temperatures greater than 165°C.

### 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                        | VQFN (RYT) |                 | UNIT |
|-------------------------------|----------------------------------------|------------|-----------------|------|
|                               |                                        | JEDEC PCB  | TPS6299xEVM-xxx |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance | 97.2       | 73.5            | °C/W |

## 7.4 Thermal Information (continued)

| THERMAL METRIC <sup>(1)</sup> |                                              | VQFN (RYT) |                 | UNIT |
|-------------------------------|----------------------------------------------|------------|-----------------|------|
|                               |                                              | JEDEC PCB  | TPS6299xEVM-xxx |      |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 74.4       | N/A             | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 25         | N/A             | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 2.7        | 4.3             | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 24.7       | 28              | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.5 Electrical Characteristics

$V_I = 3\text{ V to }10\text{ V}$ ,  $T_J = -40^\circ\text{C to }+165^\circ\text{C}$ , Typical values at  $V_I = 6\text{ V}$  and  $T_A = 25^\circ\text{C}$  unless otherwise noted

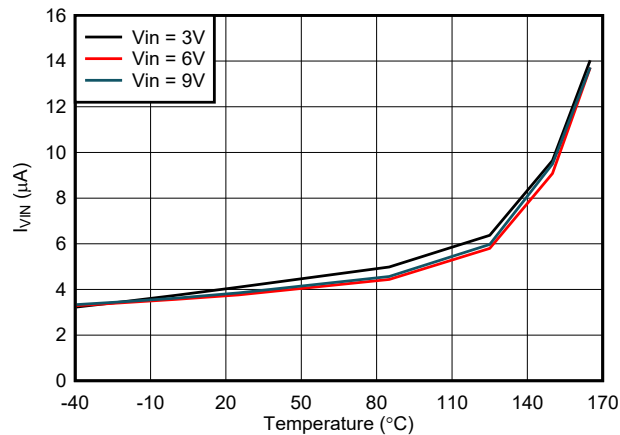
| PARAMETER                      |                                               | TEST CONDITIONS                                                                               | MIN   | TYP   | MAX   | UNIT          |
|--------------------------------|-----------------------------------------------|-----------------------------------------------------------------------------------------------|-------|-------|-------|---------------|
| <b>SUPPLY</b>                  |                                               |                                                                                               |       |       |       |               |
| $I_Q$                          | Operating Quiescent Current (Power Save Mode) | $I_{out} = 0\text{ mA}$ device not switching                                                  |       | 4     |       | $\mu\text{A}$ |
| $I_{Q,PWM}$                    | Operating Quiescent Current (PWM Mode)        | $V_{IN} = 6\text{ V}$ , $V_{OUT} = 1.2\text{ V}$ ; $I_{out} = 0\text{ mA}$ , device switching |       | 8     |       | mA            |
| $I_{SD}$                       | Shutdown current into VIN pin                 | $EN = 0\text{ V}$ ,                                                                           |       | 0.27  | 3.5   | $\mu\text{A}$ |
| $V_{UVLO}$                     | Under Voltage Lock-Out                        | $V_{IN}$ rising,                                                                              | 2.85  | 2.925 | 3.0   | V             |
|                                | Under Voltage Lock-Out                        | $V_{IN}$ falling                                                                              | 2.71  | 2.79  | 2.87  | V             |
| $V_{UVLO}$                     | Under Voltage Lock-Out Hysteresis             |                                                                                               |       | 130   |       | mV            |
| <b>CONTROL &amp; INTERFACE</b> |                                               |                                                                                               |       |       |       |               |
| $I_{LKG}$                      | EN Input leakage current                      | $EN = 5\text{ V}$                                                                             |       | 10    | 310   | nA            |
| $V_{IH,MODE}$                  | High-Level Input Voltage at MODE/S-CONF Pin   |                                                                                               | 1.0   |       |       | V             |
| $V_{IL,MODE}$                  | Low-Level Input Voltage at MODE/S-CONF Pin    |                                                                                               |       |       | 0.15  | V             |
| $T_{SD}$                       | Thermal Shutdown Threshold                    | $T_J$ rising                                                                                  | 168   | 175   | 185   | °C            |
|                                | Thermal Shutdown Hysteresis                   | $T_J$ falling                                                                                 |       | 12.5  |       |               |
| $V_{IH}$                       | High-level input voltage at EN-Pin            |                                                                                               | 0.97  | 1.0   | 1.03  | V             |
| $V_{IL}$                       | Low-level input voltage at EN-Pin             |                                                                                               | 0.820 | 0.850 | 0.880 | V             |
| $V_{PG}$                       | Power good fthreshold                         | $V_{FB}$ rising, referenced to $V_{FB}$ nominal                                               | 93%   | 96%   | 99%   |               |
|                                |                                               | $V_{FB}$ falling, referenced to $V_{FB}$ nominal                                              | 88%   | 92%   | 96%   |               |
| $V_{PG,HYS}$                   | Power good threshold hysteresis               |                                                                                               | 1.5%  | 3.5%  | 6%    |               |
| $V_{PG,OL}$                    | Low-level output voltage at PG pin            | $I_{SINK} = 1\text{ mA}$                                                                      |       |       | 0.4   | V             |
| $I_{PG,LKG}$                   | Input leakage current into PG pin             | $V_{PG} = 5\text{ V}$ ,                                                                       |       | 25    | 550   | nA            |
| $t_{PG,DLY}$                   | Power good delay time                         | $V_{FB}$ rising and falling                                                                   |       | 32    |       | $\mu\text{s}$ |
| $C_{SET}$                      | Maximum Capacitance connected to VSET pin     |                                                                                               |       |       | 30    | pF            |
| <b>POWER SWITCHES</b>          |                                               |                                                                                               |       |       |       |               |
| $I_{LKG,SW}$                   | Leakage current into SW-Pin                   | $EN = 0\text{ V}$ , $V_{SW} = V_{OS} = 5.5\text{ V}$ , $T_J$ up to $150^\circ\text{C}$        |       | 2     | 7     | $\mu\text{A}$ |
| $R_{DS,ON}$                    | High-side FET on resistance                   | $V_{IN} > 4\text{ V}$ , $I_{SW} = 500\text{ mA}$                                              |       | 62    | 111   | m $\Omega$    |
|                                | Low-side FET on resistance                    | $V_{IN} > 4\text{ V}$ , $I_{SW} = 500\text{ mA}$                                              |       | 22    | 41    |               |
| $I_{LIM}$                      | High-side FET current limit                   |                                                                                               | 4     | 4.4   | 5     | A             |
| $I_{LIM}$                      | Low-side FET current limit                    |                                                                                               | 3.8   | 4.3   | 4.8   | A             |
| $I_{LIM,SINK}$                 | Low-side FET sink current limit               |                                                                                               | 1.3   | 1.7   | 2.5   | A             |

## 7.5 Electrical Characteristics (continued)

$V_I = 3\text{ V to }10\text{ V}$ ,  $T_J = -40^\circ\text{C to }+165^\circ\text{C}$ , Typical values at  $V_I = 6\text{ V}$  and  $T_A = 25^\circ\text{C}$  unless otherwise noted

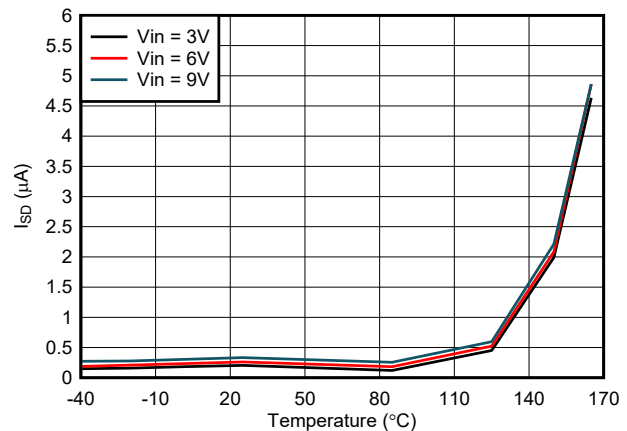
| PARAMETER                        |                                         | TEST CONDITIONS                                                                                                                                                   | MIN    | TYP     | MAX    | UNIT          |
|----------------------------------|-----------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|---------|--------|---------------|
| $f_{\text{SW}}$                  | Switching frequency                     | 2.5-MHz selection                                                                                                                                                 |        | 2.5     |        | MHz           |
| $T_{\text{ON(MIN)}}$             | Minimum On-time                         |                                                                                                                                                                   |        | 30      |        | ns            |
| $f_{\text{SW}}$                  | Switching frequency                     | 1.0-MHz selection                                                                                                                                                 |        | 1.0     |        | MHz           |
| <b>OUTPUT</b>                    |                                         |                                                                                                                                                                   |        |         |        |               |
| $V_O$                            | Output Voltage Regulation               | VSET Configuration selected, $T_J = 25^\circ\text{C}$                                                                                                             | -1%    |         | +1%    |               |
| $V_O$                            | Output Voltage Regulation               | VSET Configuration selected                                                                                                                                       | -1.5%  |         | +1.5%  |               |
| $V_{\text{FB}}$                  | Feedback Regulation Voltage             | Adjustable Configuration selected                                                                                                                                 |        | 0.6     |        | V             |
| $V_{\text{FB}}$                  | Feedback Voltage Regulation             | FB-Option selected. $T_J = 25^\circ\text{C}$ .                                                                                                                    | -0.6%  |         | +0.6%  |               |
| $V_{\text{FB}}$                  | Feedback Voltage Regulation             | FB-Option selected                                                                                                                                                | -1.25% |         | +1.25% |               |
| $I_{\text{FB}}$                  | Input leakage current into FB pin       | Adjustable configuration, $V_{\text{FB}} = 0.6\text{ V}$                                                                                                          |        | 1       | 70     | nA            |
| $T_{\text{delay}}$               | Start-up delay time                     | $I_O = 0\text{ mA}$ , time from EN=HIGH until start switching, Adjustable Configuration selected                                                                  |        | 600     | 1400   | $\mu\text{s}$ |
|                                  | Start-up delay time                     | $I_O = 0\text{ mA}$ , time from EN=HIGH until start switching, VSET Configuration selected. The typical value is based on the first option of VSET configuration. |        | 650     | 1850   | $\mu\text{s}$ |
| $T_{\text{SS}}$                  | Soft-Start time                         | $I_O = 0\text{ mA}$ after $T_{\text{delay}}$ , from 1 <sup>st</sup> switching pulse until target $V_O$ , $C_{\text{SS}} = \text{Open}$                            |        | 150     |        | $\mu\text{s}$ |
| $I_{\text{SS}}$                  | SS/TR source current                    |                                                                                                                                                                   | 2.25   | 2.5     | 2.75   | $\mu\text{A}$ |
| $V_{\text{FB}}/V_{\text{SS/TR}}$ | Tracking Gain, Adjustable Configuration |                                                                                                                                                                   |        | 0.75    |        |               |
| $V_{\text{FB}}/V_{\text{SS/TR}}$ | Tracking Gain tolerance                 |                                                                                                                                                                   |        | $\pm 8$ |        | mV            |
| $R_{\text{DISCH}}$               | Active Discharge Resistance             | Discharge = ON - Option Selected, EN = LOW                                                                                                                        |        | 7.5     | 30     | $\Omega$      |

## 7.6 Typical Characteristics

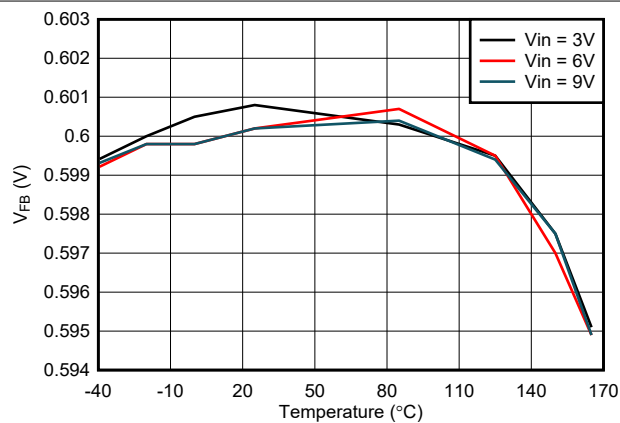


Measured with the device not switching

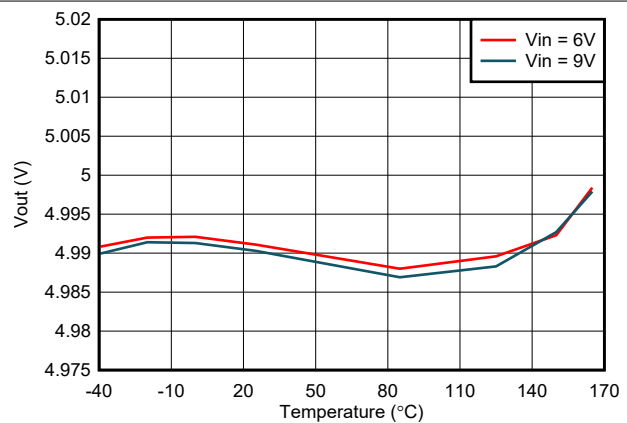
**Figure 7-1. Quiescent Current vs Temperature**



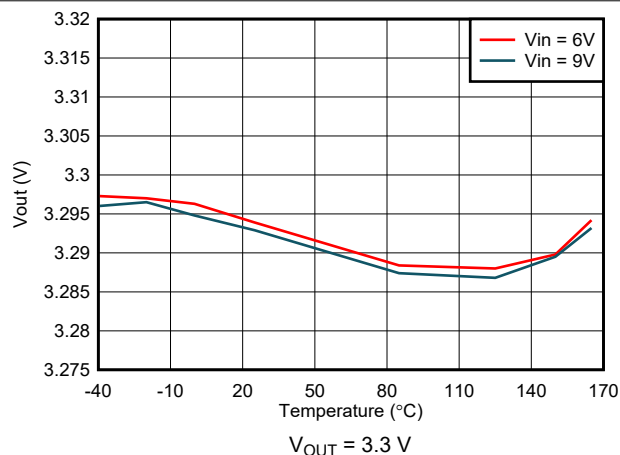
**Figure 7-2. Shutdown Current vs Temperature**



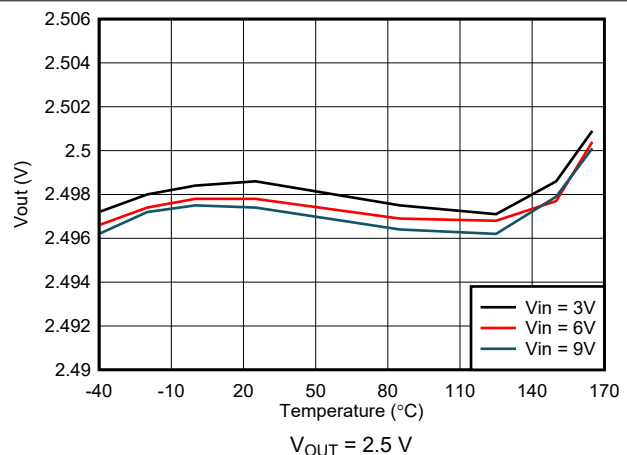
**Figure 7-3. Feedback Voltage Accuracy - External Feedback Selected**



**Figure 7-4. Output Voltage Accuracy - VSET Selected**



**Figure 7-5. Output Voltage Accuracy - VSET Selected**



**Figure 7-6. Output Voltage Accuracy - VSET Selected**



## 7.6 Typical Characteristics (continued)

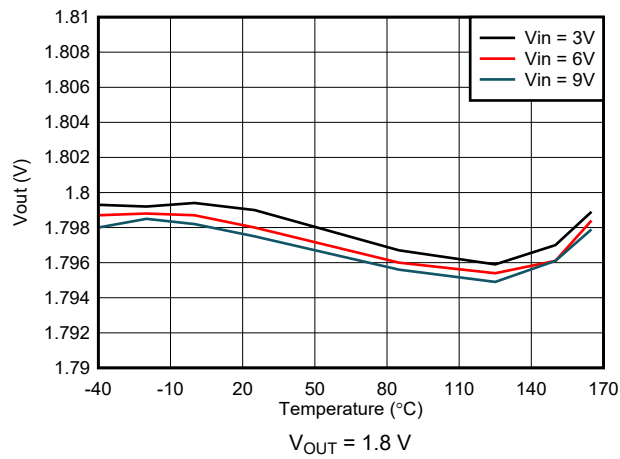


Figure 7-7. Output Voltage Accuracy - VSET Selected

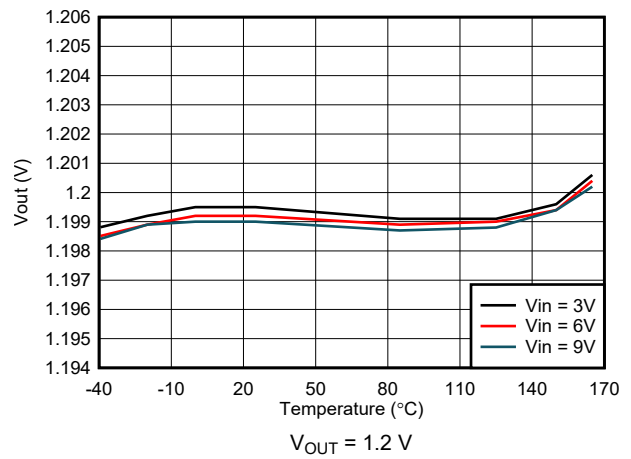


Figure 7-8. Output Voltage Accuracy - VSET Selected

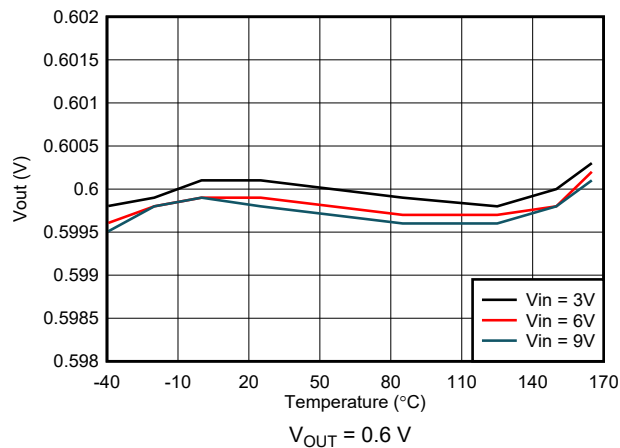


Figure 7-9. Output Voltage Accuracy - VSET Selected

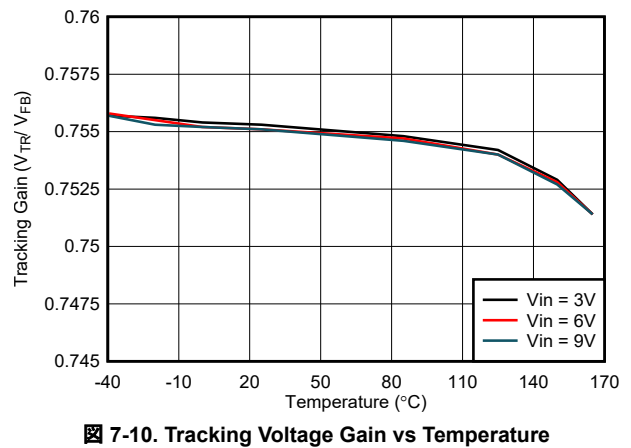


Figure 7-10. Tracking Voltage Gain vs Temperature

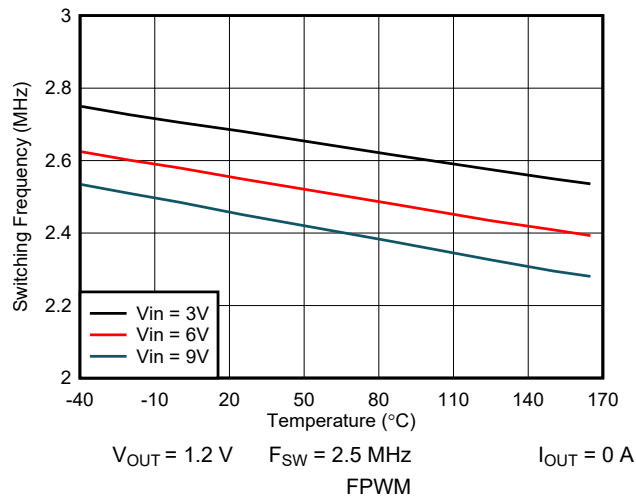


Figure 7-11. Switching Frequency vs Temperature

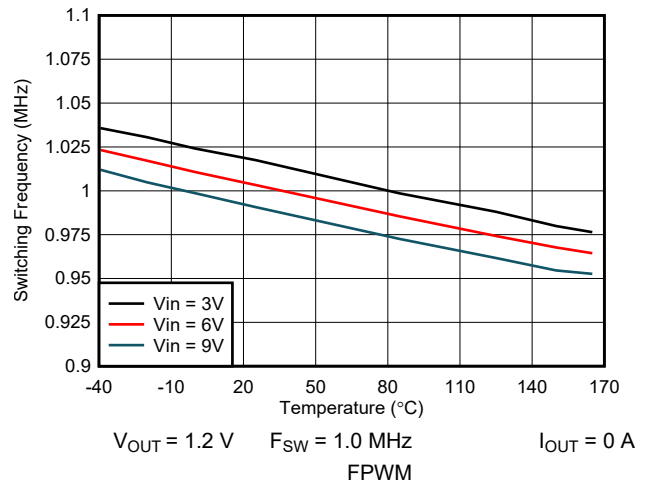


Figure 7-12. Switching Frequency vs Temperature

## 7.6 Typical Characteristics (continued)

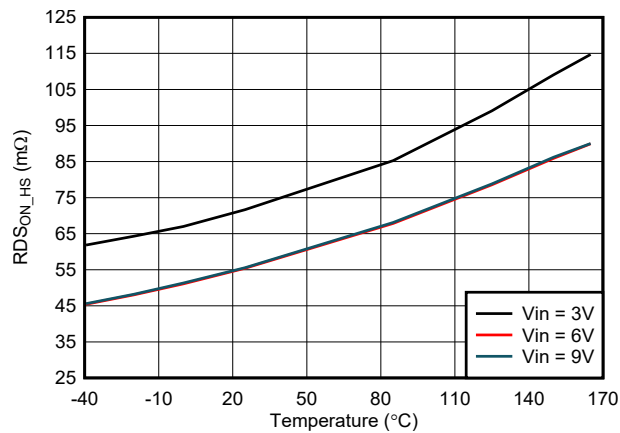


Figure 7-13. High Side  $R_{DS(on)}$  vs Temperature

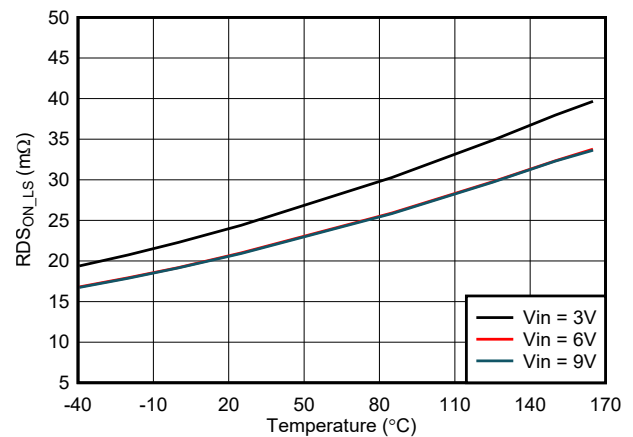


Figure 7-14. Low Side  $R_{DS(on)}$  vs Temperature

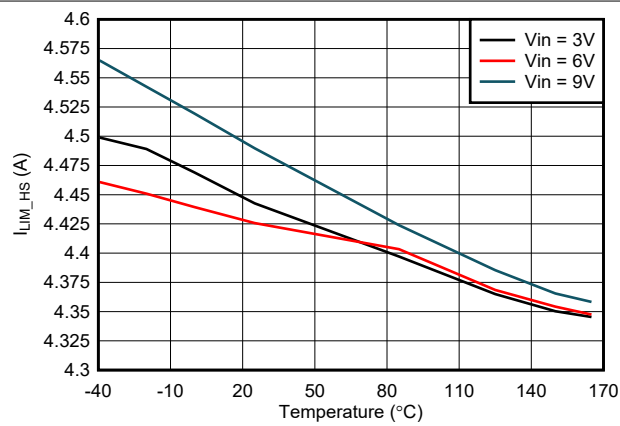


Figure 7-15. High Side  $I_{LIM}$  vs Temperature

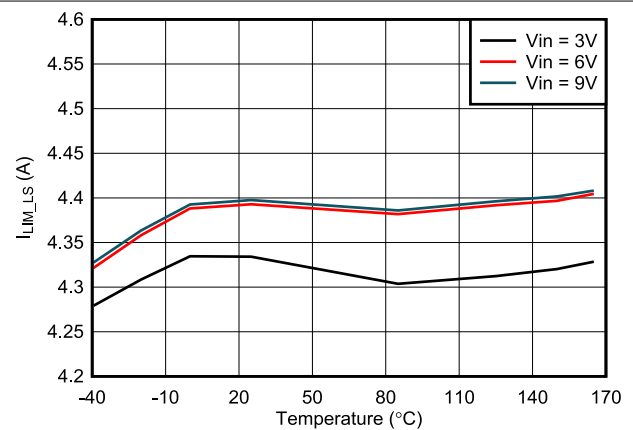


Figure 7-16. Low Side  $I_{LIM}$  vs Temperature

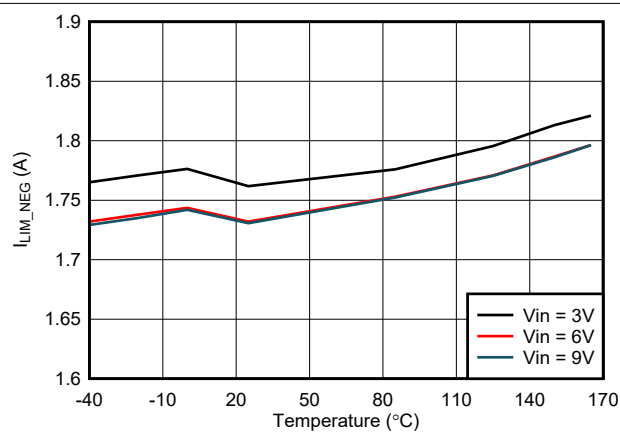


Figure 7-17. Negative  $I_{LIM}$  vs Temperature

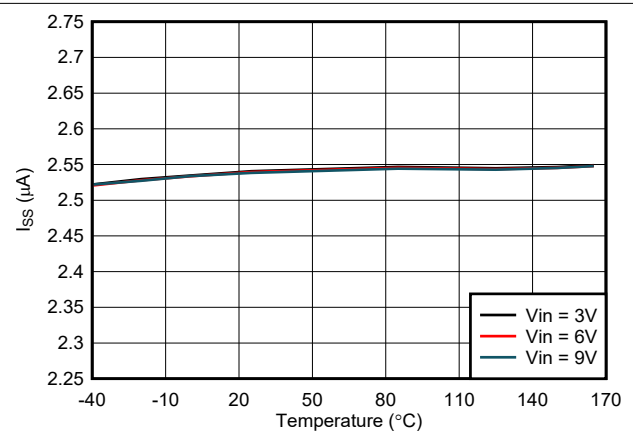
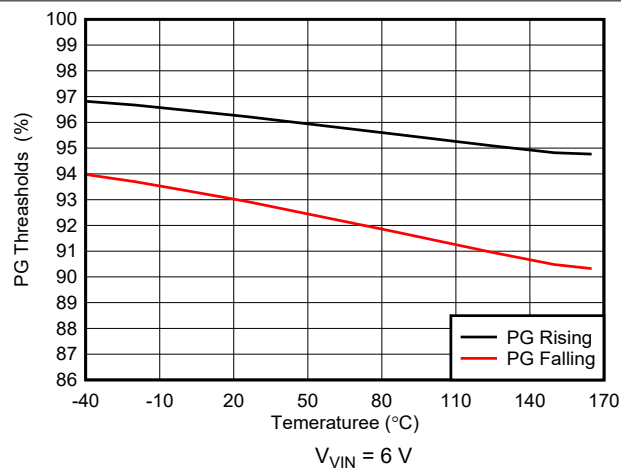
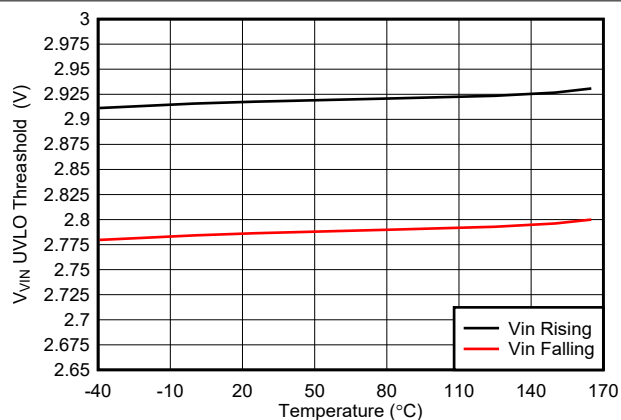


Figure 7-18. Soft Start Current vs Temperature

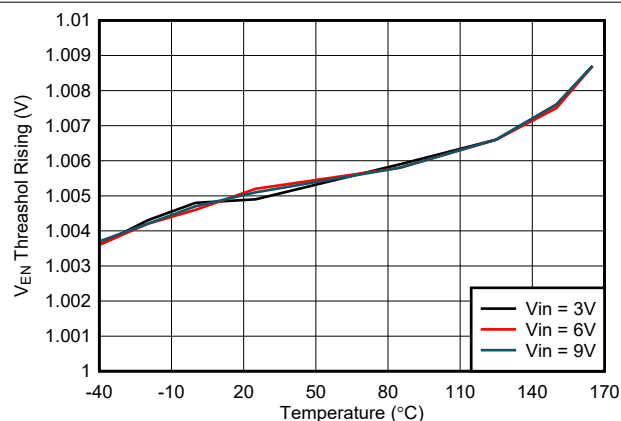
## 7.6 Typical Characteristics (continued)



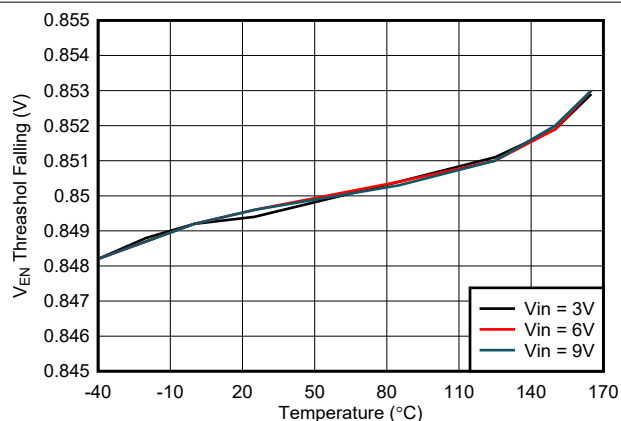
7-19. Power Good Thresholds vs Temperature



7-20.  $V_{VIN}$  UVLO Thresholds vs Temperature



7-21. Percise EN Threshold vs Temperature



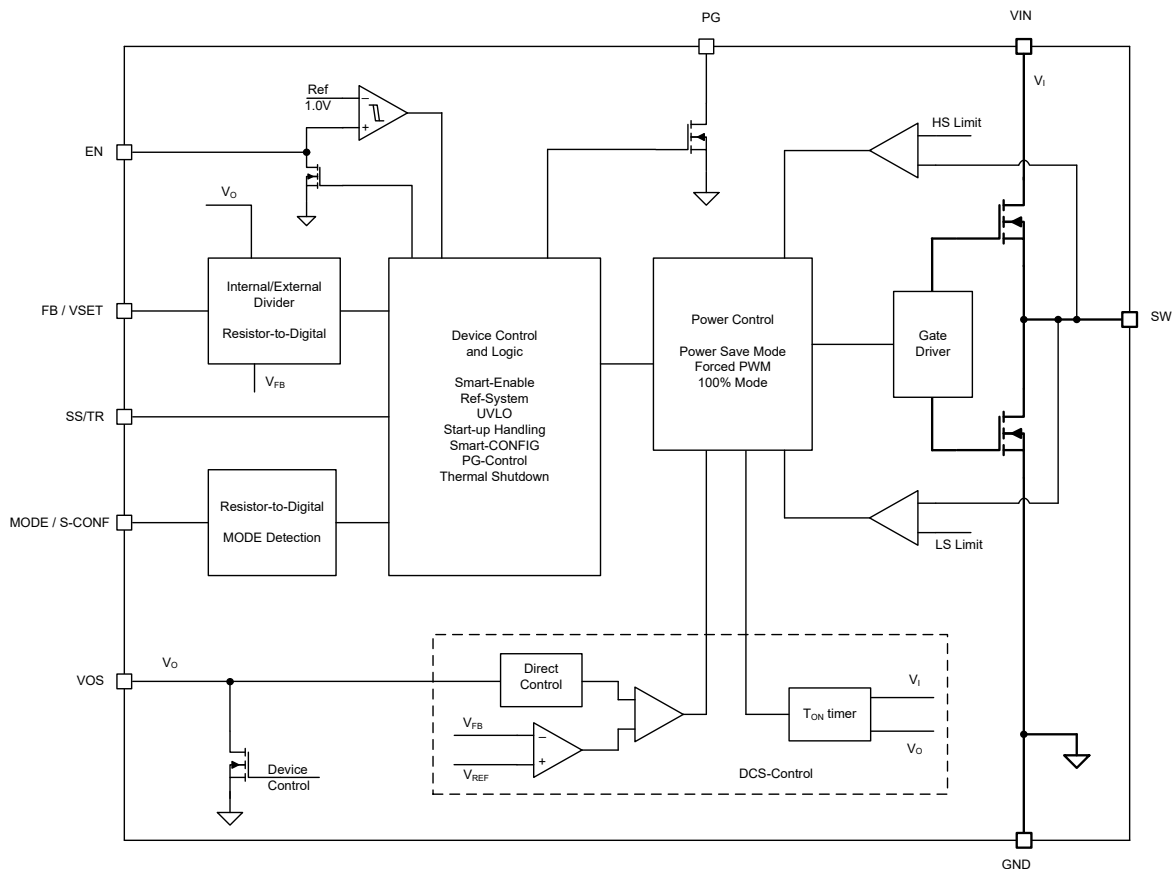
7-22. Percise EN Threshold vs Temperature

## 8 Detailed Description

### 8.1 Overview

The TPS62993-Q1 synchronous switched mode power converters are based on DCS-Control (Direct Control with Seamless Transition into power save mode). DCS-Control is an advanced regulation topology that combines the advantages of hysteretic, voltage mode, and current mode control. This control loop takes information about output voltage changes and feeds the information directly to a fast comparator stage. DCS-Control sets the switching frequency, which is constant for steady-state operating conditions, and provides immediate response to dynamic load changes. To get accurate DC load regulation, a voltage feedback loop is used. The internally compensated regulation network achieves fast and stable operation with small external components and low-ESR capacitors.

### 8.2 Functional Block Diagram



## 8.3 Feature Description

### 8.3.1 Mode Selection and Device Configuration MODE/S-CONF

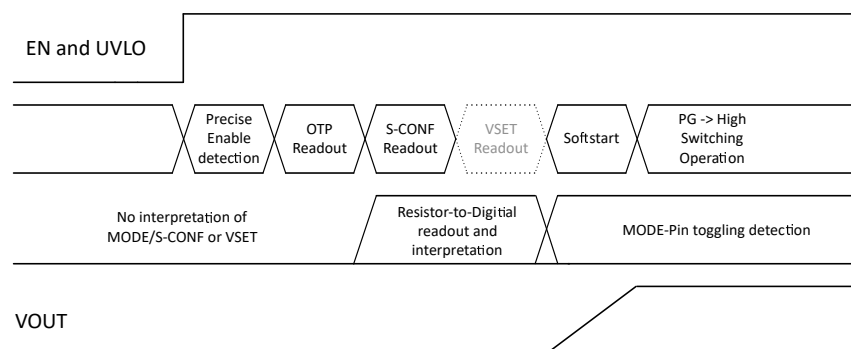
With MODE/S-CONF (SmartConfig), this device features an input with two functions. This pin can be used to customize the device behavior in two ways:

- Select the device mode (Forced PWM or Auto PFM /PWM with AEE operation) with a HIGH-level or LOW-level.
- Select the device configuration (switching frequency, internal or external feedback, output discharge, and auto PFM/PWM mode) by connecting a single resistor to the MODE/S-CONF pin.

The TPS62993-Q1 interprets this pin during the start-up sequence after the internal OTP readout and before the device starts switching in soft start (see [Figure 8-1](#)). If the device reads a HIGH-level or LOW-level, the dynamic mode change is active and auto PFM/PWM or FPWM mode can be changed during operation. If the TPS62993-Q1 reads a resistor value, the device is configured according to the resistance value in [Table 8-1](#) and there is no further interpretation during operation and device mode or other configurations can only be changed by power cycling or disabling the device.

注

The MODE/S-CONF pin must not be left floating. Connect the pin high, low, or to a resistor to configure the device according to [Table 8-1](#).



**Figure 8-1. Interpretation of S-CONF and VSET Flow**

表 8-1. SmartConfig Setting Table

| #                           | Level Or Resistor Value [Ω]<br>(1) | FB/VSET<br>Pin | F <sub>sw</sub> (MHz) | Output<br>Discharge | Mode (Auto Or Forced<br>PWM) | Dynamic Mode<br>Change |
|-----------------------------|------------------------------------|----------------|-----------------------|---------------------|------------------------------|------------------------|
| Setting Options by Level    |                                    |                |                       |                     |                              |                        |
| 1                           | GND                                | External FB    | 2.5(2)                | yes                 | Auto PFM/PWM with<br>AEE     | Active                 |
| 2                           | HIGH (> V <sub>IH_MODE</sub> )     | External FB    | 2.5                   | yes                 | Forced PWM                   |                        |
| Setting Options by Resistor |                                    |                |                       |                     |                              |                        |
| 3                           | 7.15 k                             | External FB    | 2.5(2)                | no                  | Auto PFM/PWM with<br>AEE     | Not active             |
| 4                           | 8.87 k                             | External FB    | 2.5                   | no                  | Forced PWM                   |                        |
| 5                           | 11.0 k                             | External FB    | 1                     | yes                 | Auto PFM/PWM                 |                        |
| 6                           | 13.7 k                             | External FB    | 1                     | yes                 | Forced PWM                   |                        |
| 7                           | 16.9 k                             | External FB    | 1                     | no                  | Auto PFM/PWM                 |                        |
| 8                           | 21.0 k                             | External FB    | 1                     | no                  | Forced PWM                   |                        |
| 9                           | 26.1 k                             | VSET           | 2.5(2)                | yes                 | Auto PFM/PWM with<br>AEE     |                        |
| 10                          | 32.4 k                             | VSET           | 2.5                   | yes                 | Forced PWM                   |                        |
| 11                          | 40.2 k                             | VSET           | 2.5(2)                | no                  | Auto PFM/PWM with<br>AEE     |                        |
| 12                          | 49.9 k                             | VSET           | 2.5                   | no                  | Forced PWM                   |                        |
| 13                          | 61.9 k                             | VSET           | 1                     | yes                 | Auto PFM/PWM                 |                        |
| 14                          | 76.8 k                             | VSET           | 1                     | yes                 | Forced PWM                   |                        |
| 15                          | 95.3 k                             | VSET           | 1                     | no                  | Auto PFM/PWM                 |                        |
| 16                          | 118 k                              | VSET           | 1                     | no                  | Forced PWM                   |                        |

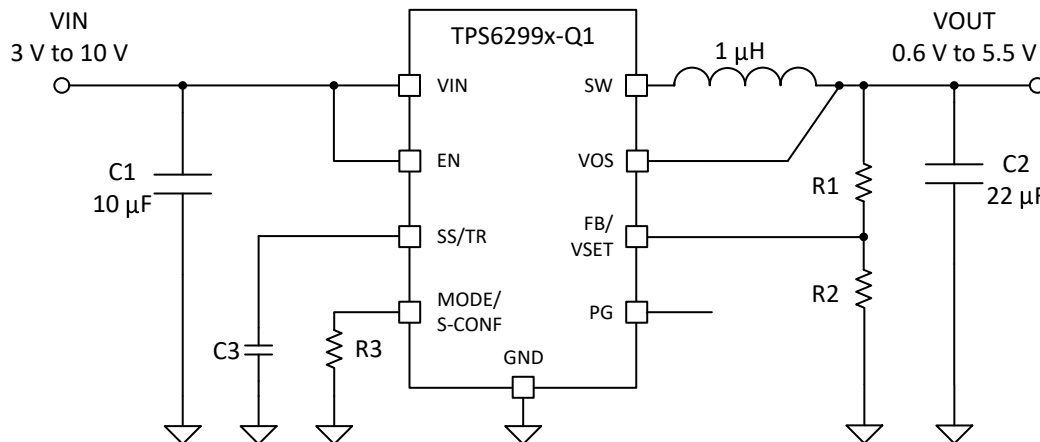
(1) E96 resistor series, 1% accuracy, temperature coefficient better or equal than ±200 ppm/°C

(2) F<sub>SW</sub> varies based on V<sub>IN</sub> and V<sub>OUT</sub>. See セクション 8.4.3 for more details.

### 8.3.2 Adjustable V<sub>O</sub> Operation (External Voltage Divider)

The TPS62993-Q1 can be programmed by the MODE/S-CONF pin to operating in a classical configuration where the FB/VSET pin is used as the feedback pin, sensing V<sub>O</sub> through an external resistive divider. The TPS62993-Q1 can also be programmed to 1 of 16 different fixed output voltages (see セクション 8.3.3).

If the device is configured to operate in the classical adjustable V<sub>O</sub> operation, the FB/VSET pin is used as the feedback pin and must sense V<sub>O</sub> through an external divider network. 図 8-2 shows the typical schematic for this configuration.

図 8-2. Adjustable V<sub>O</sub> Operation Schematic

### 8.3.3 Selectable $V_O$ Operation (VSET and Internal Voltage Divider)

If the device is configured to VSET operation,  $V_O$  is sensed only through the VOS pin by an internal resistor divider. The target  $V_O$  is programmed by an external resistor ( $R_{VSET}$ ) connected between the VSET pin and GND. 図 8-3 shows the typical schematic for this configuration.

**注意**

The MODE/S-CONF pin must not be configured for external feedback operation (see 表 8-1) if only  $R_{VSET}$  ( $R_2$  as shown in 図 8-3) is populated. This causes the output voltage to become unregulated and can damage to the device or surrounding circuitry.

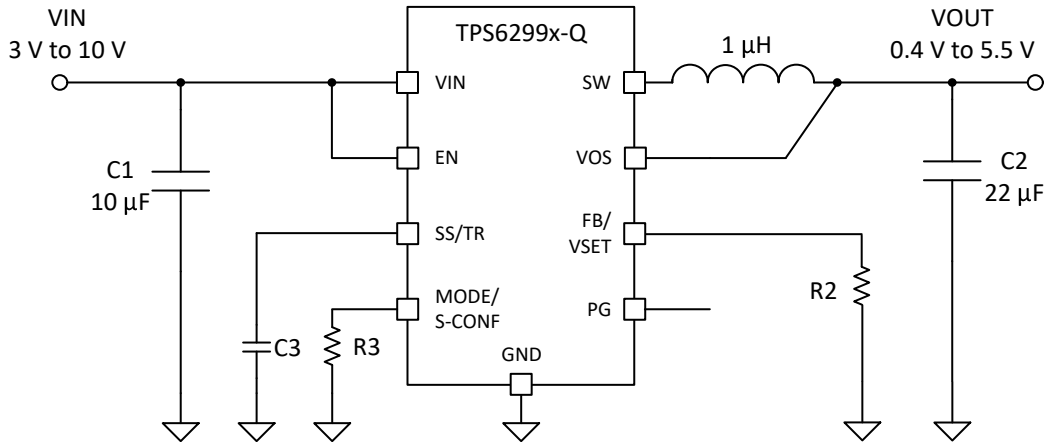


図 8-3. Selectable  $V_O$  Operation Schematic

表 8-2. VSET Selection Table

| #  | Level Or Resistor Value [ $\Omega$ ] <sup>(1)</sup> | Target $V_O$ [V] |
|----|-----------------------------------------------------|------------------|
| 1  | GND                                                 | 1.2              |
| 2  | 4.64 k                                              | 0.4              |
| 3  | 5.76 k                                              | 0.6              |
| 4  | 7.15 k                                              | 0.8              |
| 5  | 8.87 k                                              | 1.0              |
| 6  | 11.0 k                                              | 1.1              |
| 7  | 13.7 k                                              | 1.3              |
| 8  | 16.9 k                                              | 1.35             |
| 9  | 21.0 k                                              | 1.8              |
| 10 | 26.1 k                                              | 1.9              |
| 11 | 40.2 k                                              | 2.5              |
| 12 | 61.9 k                                              | 3.8              |
| 13 | 76.8 k                                              | 5.0              |
| 14 | 95.3 k                                              | 1.25             |
| 15 | 118.0 k                                             | 5.5              |
| 16 | 249.00 k or larger/Open                             | 3.3              |

(1) E96 resistor series, 1% accuracy, temperature coefficient better or equal than  $\pm 200$  ppm/ $^{\circ}\text{C}$

### 8.3.4 Soft Start and Tracking (SS/TR)

With the SS/TR pin, the user can adjust the soft-start behavior or track an external voltage source (see セクション 8.3.4.1 for operation details).

The internal soft-start circuitry controls the output voltage slope during start-up. This avoids excessive inrush current and makes sure there is a controlled output voltage rise time. The soft-start circuitry also prevents unwanted voltage drops from high impedance power sources or batteries. When EN is set high to start operation, the device starts switching after the start-up delay, while the internal reference, and hence  $V_O$ , rises with a slope controlled by the 2.5µA (typical)  $I_{SS}$  current source and an external capacitor connected to the SS/TR pin and the 2.5µA (typical)  $I_{SS}$  current source.

注

Shorting or pulling the SS/TR pin LOW externally prevents the device from switching as this sets the internal reference voltage to 0 V.

注

Leaving the SS/TR pin unconnected provides the fastest start-up response, but this can result in some output voltage overshoot depending on the  $V_{out}$  value, load current, and external component sizes. Adding or increasing the soft-start capacitor ( $C_{SS}$ ) minimizes or removes the voltage overshoot.

If the device is set to shut down ( $EN = GND$ ), undervoltage lockout, or thermal shutdown, an internal resistor pulls the SS/TR pin down to make sure there is a proper low level. Returning from those states causes a new start-up sequence as set by the SS/TR connection.

#### 8.3.4.1 Tracking Function

If a tracking function is desired, the SS/TR pin can be used for this purpose by connecting it to an external tracking voltage. The output voltage tracks that voltage with the typical gain and offset as specified in the [Electrical Characteristics](#).

注

In forced PWM (FPWM) mode the output voltage increases and decreases with any changes in the tracking voltage, but in auto PFM (power save) mode, the output voltage only decreases based on the load current.

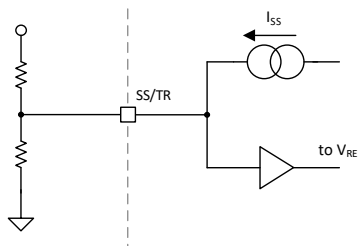


图 8-4. Tracking Operation Simplified Schematic

$$V_{FB} = 0.75 \times V_{SS/TR} \quad (1)$$

When the SS/TR pin voltage is above 0.8 V, the internal voltage is clamped and the device goes to normal regulation. This action works for rising and falling tracking voltages with the same behavior, as long as the input voltage is inside the recommended operating conditions. For decreasing the SS/TR pin voltage in PFM mode, the device does not sink current from the output. The resulting decrease of the output voltage can therefore be slower than the SS/TR pin voltage if the load is light. When driving the SS/TR pin with an external voltage, do not exceed the voltage rating of the SS/TR pin, which is 6 V. The SS/TR pin is internally connected with a resistor to GND when  $EN = 0$ .

If the input voltage drops below undervoltage lockout, the output voltage goes to zero, independent of the tracking voltage. 图 8-5 shows how to connect devices to get ratiometric and simultaneous sequencing by using the tracking function. See [セクション 9.4.3](#) in the systems examples.



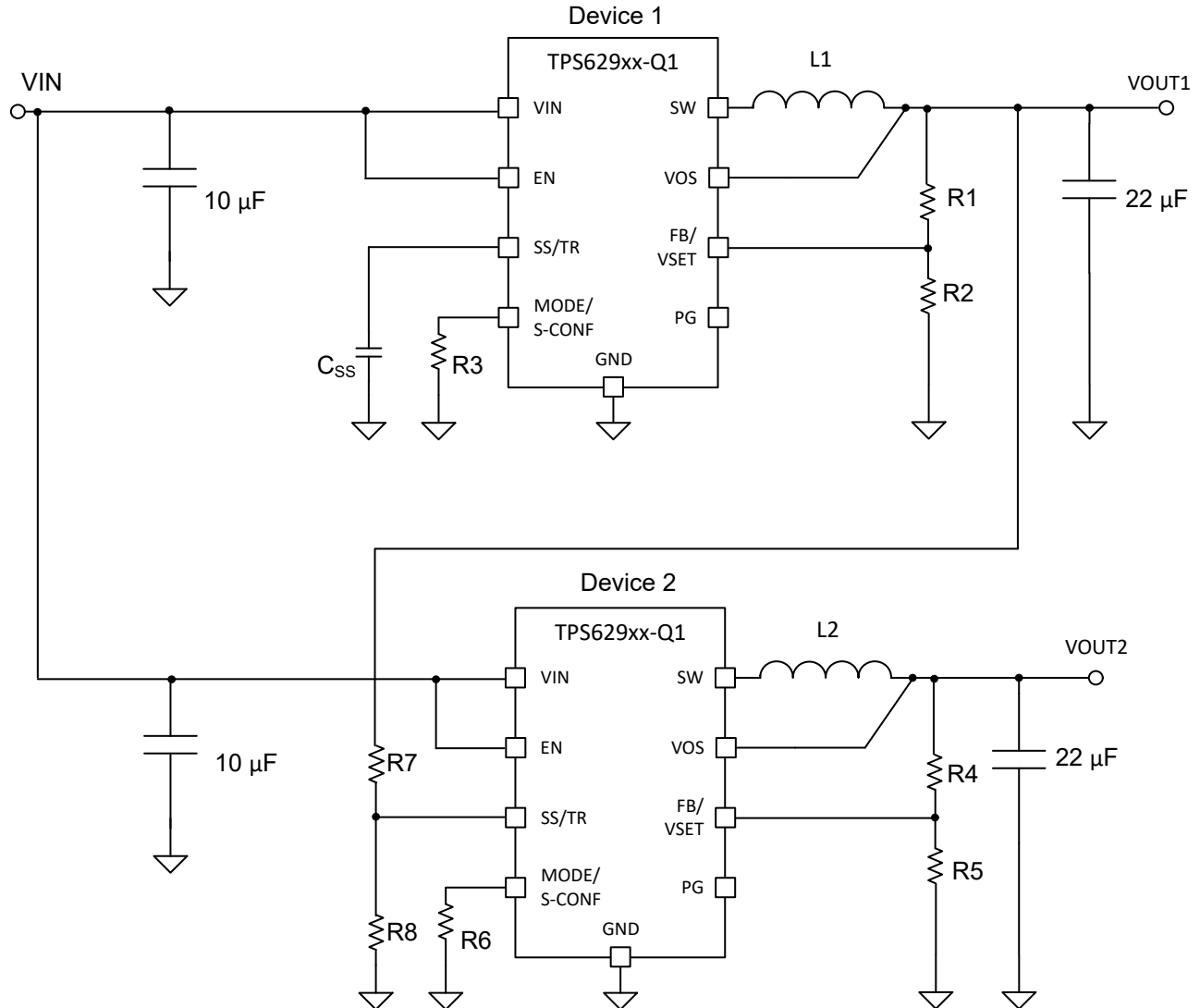


图 8-5. Schematic for Ratiometric and Simultaneous Start-Up

The resistive divider of R7 and R8 can be used to change the ramp rate of VOUT2 to be faster, slower, or the same as VOUT1.

A sequential start-up is achieved by connecting the PG pin of VOUT of device 1 to the EN pin of device 2. PG requires a pullup resistor. Ratiometric start-up sequence happens if both supplies are sharing the same soft-start capacitor. 式 18 gives the soft-start time, though the SS/TR current has to be doubled. Details about these and other tracking and sequencing circuits are found in the [Sequencing and Tracking With the TPS621-Family and TPS821-Family](#) application report.

#### 注

If the voltage at the FB pin is below its typical value of 0.6 V, the output voltage accuracy can have a wider tolerance than specified. The current of 2.5 μA out of the SS/TR pin also has an influence on the tracking function, especially for high resistive external voltage dividers on the SS/TR pin.

### 8.3.5 Smart Enable with Precise Threshold

The voltage applied at the enable pin of the TPS62993-Q1 is compared to a fixed threshold rising voltage. This allows the user to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a power-up delay.

The precise enable input allows the user to program the undervoltage lockout by adding a resistor divider to the input of the EN pin.

The enable input threshold for a falling edge is lower than the rising edge threshold. The TPS62993-Q1 starts operation when the rising threshold is exceeded. For proper operation, the EN pin must be terminated and must not be left floating. Pulling the EN pin low forces the device into shutdown. In this mode, the internal high-side and low-side MOSFETs are turned off and the entire internal control circuitry is switched off.

An internal resistor pulls the EN pin to GND when the device is disabled and avoids the pin to be floating (after the device is enabled, the pulldown is removed). This prevents an uncontrolled start-up of the device in case the EN pin cannot be driven to a low level safely. With EN low, the device is in shutdown mode. The device is turned on with EN set to a high level. The pulldown control circuit disconnects the pulldown resistor on the EN pin after the internal control logic and the reference have been powered up. With EN set to a low level, the device enters shutdown mode and the pulldown resistor is activated again.

### 8.3.6 Power Good (PG)

The TPS62993-Q1 has a built-in power-good (PG) feature to indicate whether the output voltage has reached its target and the device is ready. The PG signal can be used for start-up sequencing of multiple rails. The PG pin is an open-drain output that requires a pullup resistor to any voltage up to the recommended input voltage level. PG is low when the device is turned off due to EN, UVLO (undervoltage lockout), or thermal shutdown.  $V_{IN}$  must remain present for the PG pin to stay low.

If the power-good output is not used, TI recommends to tie to GND or leave it open.

**表 8-3. Power Good Indicator Functional Table**

| Logic Signals                  |        |                  |                     | PG Status      |
|--------------------------------|--------|------------------|---------------------|----------------|
| $V_{IN}$                       | EN Pin | Thermal Shutdown | $V_{OUT}$           |                |
| $V_{IN} > UVLO$                | HIGH   | No               | $V_{OUT}$ on target | High Impedance |
|                                |        |                  | $V_{OUT} < target$  | LOW            |
|                                | LOW    | Yes              | x                   | LOW            |
|                                |        | x                | x                   | LOW            |
| $1.8\text{ V} < V_{IN} < UVLO$ | x      | x                | x                   | LOW            |
| $V_{IN} < 1.8\text{ V}$        | x      | x                | x                   | Undefined      |

#### 注

For prebiased  $V_{OUT}$  conditions (during start-up) of 60% or more of the programmed output voltage, a minimum 250- $\mu\text{s}$  external soft start ( $C_{SS} > 0.75\text{ nF}$ ) is required. If the 250- $\mu\text{s}$  soft start minimum is not ensured and  $V_{OUT}$  is prebiased above 60% of the programmed output voltage during start-up, PG can be seen asserted "early" before  $V_{OUT}$  reaches the PG rising threshold, a glitch on PG can be observed, or both.

### 8.3.7 Output Discharge Function

The purpose of the discharge function is to make sure there is a defined down-ramp of the output voltage when the device is being disabled, and to also keep the output voltage close to 0 V when the device is off. This can be especially useful for applications with a system wide EN function that removes the output load in conjunction with disabling the power supply.

The output discharge feature is only active after the TPS62993-Q1 has been enabled at least once since the supply voltage was applied ( $V_{VIN} > UVLO$ ). The internal discharge resistor is connected to the VOS pin. The discharge function is enabled as soon as the device is disabled, in thermal shutdown, or in undervoltage lockout. The minimum supply voltage required for the discharge function to remain active typically is 2 V.

### 8.3.8 Undervoltage Lockout (UVLO)

If the input voltage drops, the undervoltage lockout prevents mis-operation of the device by switching off both the power FETs. The device is fully operational for voltages above the rising UVLO threshold and turns off if the input voltage trips below the threshold for a falling supply voltage.

### 8.3.9 Current Limit and Short-Circuit Protection

The TPS62993-Q1 is protected against overload and short-circuit events. If the inductor current exceeds the high-side FET current limit ( $I_{LIMH}$ ), the high-side switch is turned off and the low-side switch is turned on to ramp down the inductor current. The high-side FET turns on again only if the current in the low-side FET has decreased below the low-side FET current limit threshold AND the internal  $I_{LIM}$  recovery delay has expired.

#### 注

While the internal recovery delay generally keeps the switching frequency within the normal operating range of the device, the switching frequency is not tightly controlled during overload events.

Due to internal propagation delay, the actual current can exceed the static current limit during that time. The dynamic current limit is given as 式 2:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_L}{L} \times t_{pd} \quad (2)$$

where

- $I_{LIMH}$  is the static high-side FET current limit as specified in the [Electrical Characteristics](#).
- $L$  is the effective inductance at the peak current.
- $V_L$  is the voltage across the inductor ( $V_{IN} - V_{OUT}$ ).
- $t_{PD}$  is the internal propagation delay of typically 50 ns.

The current limit can exceed static values, especially if the input voltage is high and very small inductance is used. The dynamic high-side switch peak current can be calculated as follows:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_{VIN} - V_{VOUT}}{L} \times 50ns \quad (3)$$

The TPS62993-Q1 also includes a low-side negative current limit ( $I_{LIM:SINK}$ ) to protect against excessive negative currents that can occur in forced PWM mode under heavy to light load transient conditions. If the negative current in the low-side switch exceeds the  $I_{LIM:SINK}$  threshold, the low-side switch is disabled. Both the low-side and high-side switches remain off until an internal timer re-enables the high-side switch based on the selected PWM switching frequency.

#### 注意

If Forced PWM (FPWM) mode is being used, TI recommends that the inductor be sized such that the inductor ripple current,  $\Delta I_L$  (see 式 9), does not exceed 2.6 A to avoid the potential for continuous operation of the negative current limit with no output load ( $I_O = 0$  A).

### 8.3.10 High Temperature Specifications

The TPS62993-Q1 is capable of high operating junction temperatures up to 165°C. The AEC-Q100 Grade-1 maximum ambient temperature requirement ( $T_{A\_max} = 125^\circ\text{C}$ ) combined with power dissipation on integrated chips often results in device operating temperatures well above 125 °C. Additionally, although Grade 1 with extended temperature does not exist as a standard by itself, the 165°C maximum operating junction temperature allows for the TPS62993-Q1 to be used in applications with ambient temperatures upwards of 150°C that require less device power dissipation.

## 注

For more information on the different thermal metrics for semiconductor integrated circuits (ICs) including the relationship between the operating junction ( $T_J$ ) and ambient ( $T_A$ ) temperatures of a device, refer to the [Semiconductor and IC Package Thermal Metrics](#) application report.

The TPS62993-Q1 is designed to sustain these high temperatures while maintaining performance and reliability, which is accomplished by compliant electrical specifications up to  $T_J = 165^{\circ}\text{C}$ . In addition, extra reliability testing has been performed that exceeds the AEC-Q100 Grade 1 requirements.

### 8.3.11 Thermal Shutdown

The junction temperature,  $T_J$ , of the device is monitored by an internal temperature sensor. If  $T_J$  rises and exceeds the thermal shutdown threshold,  $T_{SD}$ , the device shuts down. Both the high-side and low-side power FETs are turned off and PG goes low. When  $T_J$  decreases below the hysteresis, the converter resumes normal operation, beginning with soft start. In PSM during a PFM skip pause (when both high-side and low-side FETs are off, the thermal shutdown feature is not active. A shutdown or restart is only triggered during a switching cycle. See [セクション 8.4.2](#).

## 8.4 Device Functional Modes

### 8.4.1 Forced Pulse Width Modulation (FPWM) Operation

The TPS62993-Q1 has two operating modes: Forced PWM (FPWM) mode discussed in this section and auto PFM and PWM as discussed in [セクション 8.4.2](#).

With the MODE/S-CONF pin configured for FPWM mode, the TPS62993-Q1 operates with pulse width modulation in continuous conduction mode (CCM) with a nominal switching frequency of either 2.5 MHz or 1.0 MHz. The frequency variation in PWM is controlled and depends on  $V_{IN}$ ,  $V_{OUT}$ , and the inductance. The on time in forced PWM mode is given by [式 4](#):

$$T_{ON} = \frac{V_{OUT}}{V_{IN}} \times \frac{1}{f_{SW}} \quad (4)$$

For very small output voltages, a minimum on time of approximately 30 ns is kept to limit switching losses. The operating frequency is thereby reduced from its nominal value, which keeps efficiency high.

### 8.4.2 Power Save Mode Operation (Auto PFM and PWM)

When the MODE/S-CONF pin is configured for power save mode (auto PFM and PWM). The device operates in PWM mode as long the output current is higher than half of the ripple current of the inductor, and seamlessly transitions to PSM operation as the load decreases. In power save mode, the device operates in PFM mode by reducing the switching frequency linearly with the load current to maintain high efficiency under light load operation. The device remains in power save mode as long as the inductor current remains discontinuous, and the transition out of PSM also occurs seamlessly when the load current increases above the DCM boundary.

In addition to operating in PFM under light load, when the 2.5 MHz  $F_{SW}$  option is selected, the TPS62993-Q1 further adjusts the on time ( $T_{ON}$ ), depending on the input voltage and the output voltage to maintain highest efficiency using the AEE function as described in [セクション 8.4.3](#).

In power save mode, the  $T_{ON}$  time can be estimated using [式 4](#) for 1 MHz and [式 8](#) for 2.5 MHz.

For higher input voltages and small output voltages, an absolute minimum on time of approximately 30 ns is kept to limit switching losses. The operating frequency is thereby reduced from its nominal value, which keeps efficiency high. Using  $T_{ON}$ , the typical peak inductor current in power save mode is approximated by [式 5](#):

$$I_{LPSM_{peak}} = \frac{V_{IN} - V_{OUT}}{L} \times T_{ON} \quad (5)$$

The output voltage ripple in power save mode is given by [式 6](#):

$$\Delta V = \frac{L \times V_{IN}^2}{200 \times C} + \left( \frac{1}{V_{IN} - V_{OUT}} + \frac{1}{V_{OUT}} \right) \quad (6)$$

where

- L is the effective inductance.
- C is the output effective capacitance.

#### 注

When  $V_{IN}$  decreases to typically 15% above  $V_{OUT}$ , the TPS62993-Q1 does not enter power save mode, regardless of the load current. The device maintains output regulation in PWM mode.

### 8.4.3 AEE (Automatic Efficiency Enhancement)

When the MODE/S-CONF pin is configured for auto PFM/PWM with AEE mode, the TPS62993-Q1 provides the highest efficiency over the entire input voltage and output voltage range by automatically adjusting the switching frequency of the converter (see [式 7](#)). To keep the efficiency high over the entire duty cycle range, the switching

frequency is adjusted while maintaining the ripple current amplitudes. This feature compensates for the very small duty cycles of high  $V_{IN}$  to low  $V_{OUT}$  conversions, which can limit the control range in other topologies.

$$F_{SW} (MHz) = 10 \times V_{OUT} \times \frac{V_{IN} - V_{OUT}}{V_{IN}^2} \quad (7)$$

Traditionally, the efficiency of a switched mode converter decreases if  $V_{OUT}$  decreases,  $V_{IN}$  increases, or both. By decreasing the switching losses at lower  $V_{OUT}$  values or higher  $V_{IN}$  values, the AEE feature provides an efficiency enhancement across various duty cycles, especially for the lower  $V_{OUT}$  values, where fixed frequency converters suffer from a significant efficiency drop.

To accomplish this, the AEE function in the TPS62993-Q1 adjusts the on time (TON) depending on the input voltage and the output voltage, and the on time in steady-state operation can be estimated as using 式 8:

$$T_{ON} (ns) = 100 \times \frac{V_{IN}}{V_{IN} - V_{OUT}} \quad (8)$$

By using the same TON configuration (see 式 9) across the entire load range in AEE mode, the inductor ripple current in AEE mode becomes effectively independent of the output voltage and can be approximated by 式 9:

$$\Delta I_L (mA) = T_{ON} \times \frac{V_{IN} - V_{OUT}}{L} = 0.1 \times \frac{V_{IN} (V)}{L (\mu H)} \quad (9)$$

The TPS62993-Q1 operates in AEE mode as long as the output current is higher than half the ripple current of the inductor. To maintain high efficiency at light loads, the device enters power save mode at the boundary to discontinuous mode (DCM), which happens when the output current becomes smaller than half the inductor ripple current.

#### 8.4.4 100% Duty-Cycle Operation

The duty cycle of the buck converter operating in PWM mode is given as  $D = V_{OUT} / V_{IN}$ . The duty cycle increases as the input voltage comes close to the output voltage and the off time gets smaller. When the minimum off time of typically 80 ns is reached, the TPS62993-Q1 scales down its switching frequency while it approaches 100% mode. In 100% mode, the device keeps the high-side switch on continuously. The high-side switch stays turned on as long as the output voltage is below the internal set point, allowing the conversion of small input to output voltage differences (for example, getting longest operation time of battery-powered applications). In 100% duty cycle mode, the low-side FET is switched off.

The minimum input voltage to maintain output voltage regulation, depending on the load current and the output voltage level, can be calculated as:

$$V_{IN (MIN)} = V_{OUT} + I_{OUT} \times (R_{DS(ON)} + R_L) \quad (10)$$

where

- $I_{OUT}$  is the output current.
- $R_{DS(on)}$  is the on-state resistance of the high-side FET.
- $R_L$  is the DC resistance of the inductor used.

#### 8.4.5 Starting into a Prebiased Load

The TPS62993-Q1 is capable of starting into a prebiased output. The device only starts switching when the internal soft-start ramp is equal or higher than the feedback voltage. If the voltage at the feedback pin is biased to a higher voltage than the nominal value, the TPS62993-Q1 does not start switching unless the voltage at the feedback pin drops to the target. See the note in セクション 8.3.6 regarding the soft-start requirement during prebiased conditions.

## 9 Application and Implementation

### 注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 9.1 Application Information

The TPS62993-Q1 devices are highly efficient, small, and highly flexible synchronous step-down DC/DC converters that are easy to use. A wide input voltage range of 3 V to 10 V supports a wide variety of inputs like 9-V supply rails, single-cell or multi-cell Li-Ion, and 5-V or 3.3-V rails.

### 9.2 Typical Application with Adjustable Output Voltage

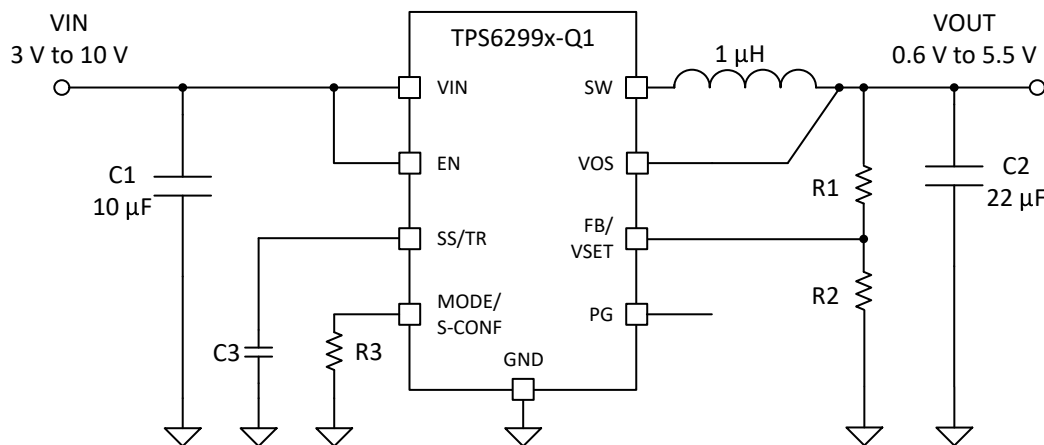


図 9-1. Typical Application Circuit

#### 9.2.1 Design Requirements

表 9-1. List of Components

| Reference | Description                                                         | Manufacturer                               |
|-----------|---------------------------------------------------------------------|--------------------------------------------|
| IC        | 10 V, 3-A step-down converter                                       | TPS62993-Q1 series; Texas Instruments      |
| L         | 1-µH inductor                                                       | XGL4020-102; Coilcraft                     |
| CIN       | 10 µF, 25 V, Ceramic, X8R                                           | CGA6P1X8R1E106K250AE, TDK                  |
| COUT      | 22 µF, 16 V, Ceramic, X8L                                           | CGA6P1X8L1C226M250AC, TDK                  |
| CSS       | Depends on soft-start time; see <a href="#">セクション 9.2.2.3.3.3</a> . | AEC-Q200 qualified, 16 V, Ceramic, X8R     |
| R1        | Depending on $V_{OUT}$ ; see <a href="#">セクション 9.2.2.2</a> .        | AEC-Q200 qualified, Standard 1% metal film |
| R2        | Depending on $V_{OUT}$ ; see <a href="#">セクション 9.2.2.2</a> .        | AEC-Q200 qualified, Standard 1% metal film |
| R3        | Depending on device setting, see <a href="#">セクション 8.3.1</a> .      | AEC-Q200 qualified, Standard 1% metal film |

### 9.2.2 Detailed Design Procedure

#### 9.2.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS62993-Q1 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.

### 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH](http://www.ti.com/WEBENCH).

#### 9.2.2.2 Programming the Output Voltage

When the MODE/S\_CONF pin is configured for external feedback, the output voltage of the TPS62993-Q1 is fully adjustable. It can be programmed for output voltages from 0.6 V to 5.5 V using a resistor divider from V<sub>OUT</sub> to GND. The voltage at the FB pin is regulated to 600 mV. The value of the output voltage is set by the selection of the resistor divider from 式 11. TI recommends to choose resistor values that allow a current of at least 2 µA, meaning the value of R2 must not exceed 400 kΩ. Lower resistor values are recommended for highest accuracy and most robust design.

$$R_1 = R_2 \times \left( \frac{V_{OUT}}{V_{FB}} - 1 \right) \quad (11)$$

With typical V<sub>FB</sub> = 0.6 V:

**表 9-2. Setting the Output Voltage**

| Nominal Output Voltage | R1      | R2      | Exact Output Voltage |
|------------------------|---------|---------|----------------------|
| 0.75 V                 | 24.9 kΩ | 100 kΩ  | 0.749 V              |
| 1.2 V                  | 100 kΩ  | 100 kΩ  | 1.2 V                |
| 1.5 V                  | 150 kΩ  | 100 kΩ  | 1.5 V                |
| 1.8 V                  | 200 kΩ  | 100 kΩ  | 1.8 V                |
| 2.0 V                  | 49.9 kΩ | 21.5 kΩ | 1.992 V              |
| 2.5 V                  | 100 kΩ  | 31.6 kΩ | 2.498 V              |
| 3.0 V                  | 100 kΩ  | 24.9 kΩ | 3.009 V              |
| 3.3 V                  | 113 kΩ  | 24.9 kΩ | 3.322 V              |
| 5.0V                   | 182 kΩ  | 24.9 kΩ | 4.985 V              |

#### 9.2.2.3 External Component Selection

The external components have to fulfill the needs of the application, but also the stability criteria of the control loop of the device. The TPS62993-Q1 is optimized to work within a range of external components.

##### 9.2.2.3.1 Output Filter and Loop Stability

The TPS62993-Q1 is designed to be stable with a range of L-C filter combinations. The LC output filters inductance and capacitance have to be considered together, creating a double pole responsible for the corner frequency of the converter using 式 12.

$$f_{LC} = \frac{1}{2\pi\sqrt{L \times C}} \quad (12)$$

Proven nominal values for inductance and ceramic capacitance are given in 表 9-3 and are recommended for use with the effective capacitance considered to vary by +20% and –50%. Different values can work, but care has to be taken on the loop stability, which is affected. More information including a detailed LC stability matrix can be found in the [Optimizing the TPS62130/40/50/60 Output Filter](#) application report.



**表 9-3. Recommended LC Output Filter Combinations**

|             | 4.7 $\mu$ F | 10 $\mu$ F | 22 $\mu$ F       | 47 $\mu$ F | 100 $\mu$ F      | 200 $\mu$ F      |
|-------------|-------------|------------|------------------|------------|------------------|------------------|
| 1 $\mu$ H   |             | √          | √ <sup>(1)</sup> | √          | √                | √ <sup>(3)</sup> |
| 1.5 $\mu$ H |             | √          | √                | √          | √ <sup>(3)</sup> |                  |
| 2.2 $\mu$ H |             | √          | √ <sup>(2)</sup> | √          | √ <sup>(3)</sup> |                  |
| 3.3 $\mu$ H | √           | √          | √                | √          |                  |                  |

- (1) This LC combination is the standard value and recommended for most applications with 2.5-MHz switching frequency.  
(2) This LC combination is the standard value and recommended for most applications with 1-MHz switching frequency.  
(3) Output capacitance must have a ESR of  $\geq 10$  m $\Omega$  for stable operation, see [セクション 9.4.2](#).

The TPS62993-Q1 includes an internal 3-pF feedforward capacitor, connected between the VOS and FB pins. This capacitor impacts the frequency behavior and sets a pole and zero in the control loop with the resistors of the feedback divider, per [式 13](#) and [式 14](#):

$$f_{zero} = \frac{1}{2\pi \times R_1 \times 3pF} \quad (13)$$

$$f_{pole} = \frac{1}{2\pi \times 3pF} \times \left( \frac{1}{R_1} \times \frac{1}{R_2} \right) \quad (14)$$

Although the TPS62993-Q1 devices are stable without the pole and zero being in a particular location, an external feedforward capacitor can be added to adjust their locations to the specific needs of the application can provide better performance in power save mode, improved transient response, or both. A more detailed discussion on the optimization for stability versus transient response can be found in the [Optimizing Transient Response of Internally Compensated DC-DC Converters](#) and [Feedforward Capacitor to Improve Stability and Bandwidth of TPS621/821-Family](#) application reports.

#### 9.2.2.3.2 Inductor Selection

The TPS62993-Q1 is designed for a nominal 1- $\mu$ H inductor. Larger values can be used to achieve a lower inductor current ripple, but they can have a negative impact on efficiency and transient response. Smaller values than 1  $\mu$ H cause a larger inductor current ripple, which causes larger negative inductor current in forced PWM mode at low or no output current. Therefore, TI does not recommend them at large voltages across the inductor as it is the case for high input voltages and low output voltages. Low-output current in forced PWM mode causes a larger negative inductor current peak, which can exceed the negative current limit. At low or no output current and small inductor values, the output voltage cannot be regulated any more. More detailed information on further LC combinations can be found in the [Optimizing the TPS62130/40/50/60 Output Filter](#) application report.

The inductor selection is affected by several factors like inductor ripple current, output ripple voltage, PWM-to-PFM transition point, and efficiency. In addition, the inductor selected has to be rated for appropriate saturation current and DC resistance (DCR). [式 15](#) calculates the maximum inductor current.

$$I_{L(MAX)} = I_{OUT(MAX)} + \frac{\Delta I_{L(MAX)}}{2} \quad (15)$$

$$\Delta I_{L(MAX)} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN(MAX)}}}{L_{(MIN)} \times f_{SW}} \quad (16)$$

where

- $I_{L(max)}$  is the maximum inductor current.
- $\Delta I_{L(max)}$  is the maximum peak-to-peak inductor ripple current.
- $L_{(min)}$  is the minimum effective inductor value.
- $f_{sw}$  is the actual PWM switching frequency.
- $V_{OUT}$  is the output voltage.
- $V_{IN(max)}$  is the maximum expected output voltage.

Calculating the maximum inductor current using the actual operating conditions gives the needed minimum saturation current of the inductor. TI recommends to add a margin of about 20%. A larger inductor value is also useful to get lower ripple current, but increases the transient response time and size as well. The following inductors have been used with the TPS62993-Q1 and are recommended for use:

**表 9-4. List of Inductors**

| Type          | Inductance [μH] | Current [A] <sup>(1)</sup> | Dimensions [L × B × H] mm | Manufacturer |
|---------------|-----------------|----------------------------|---------------------------|--------------|
| XGL4020-102ME | 1.0 μH, ±20%    | 8.8                        | 4.0 × 4.0 × 2.1           | Coilcraft    |
| XGL4020-222ME | 2.2 μH, ±20%    | 6.2                        | 4.0 × 4.0 × 2.1           | Coilcraft    |

(1)  $I_{SAT}$  at 30% drop

The inductor value also determines the load current at which power save mode is entered:

$$I_{Load(PSM)} = \frac{1}{2} \times \Delta I_L \quad (17)$$

### 9.2.2.3.3 Capacitor Selection

#### 9.2.2.3.3.1 Output Capacitor

The recommended value for the output capacitor is 22 μF. The architecture of the TPS62993-Q1 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, TI recommends the use of X7R or X8R dielectric capacitors. Using a higher value has advantages like smaller voltage ripple and a tighter DC output accuracy in power save mode (see the [Optimizing the TPS62130/40/50/60 Output Filter](#) application report).

In power save mode, the output voltage ripple depends on the following:

- Output capacitance
- ESR
- ESL
- Peak inductor current

Using ceramic capacitors provides small ESR, ESL, and low ripple. The output capacitor must be as close as possible to the device.

For large output voltages, the DC bias effect of ceramic capacitors is large and the effective capacitance has to be observed.

#### 9.2.2.3.3.2 Input Capacitor

For most applications, 10 μF nominal is sufficient and is recommended, though a larger value reduces input current ripple further. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. TI recommends a low-ESR multilayer ceramic capacitor (MLCC) for best filtering and must be placed between VIN and GND as close as possible to those pins.

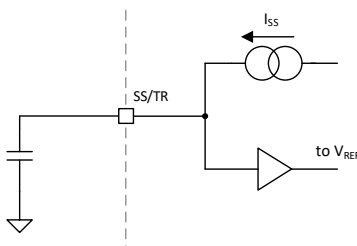
**表 9-5. List of Capacitors**

| Type <sup>(1)</sup>  | Nominal Capacitance [μF] | Voltage Rating [V] | Size | Manufacturer |
|----------------------|--------------------------|--------------------|------|--------------|
| CGA6P1X8R1E106K250AE | 10                       | 25                 | 1210 | TDK          |
| CGA6P1X8L1C226M250AC | 22                       | 16                 | 1210 | TDK          |

(1) Lower of  $I_{RMS}$  at 40°C rise or  $I_{SAT}$  at 30% drop

#### 9.2.2.3.3.3 Soft-Start Capacitor

A capacitor connected between SS/TR pin and GND allows a user-programmable start-up slope of the output voltage.



**Figure 9-2. Soft-Start Operation Simplified Schematic**

An internal constant current source is provided to charge the external capacitance. The capacitor required for a given soft-start ramp time is given by:

$$C_{SS} = T_{SS} \times \frac{I_{SS}}{V_{REF}} \quad (18)$$

where

- $C_{SS}$  is the capacitance required at the SS/TR pin.
- $T_{SS}$  is the desired soft-start ramp time.
- $I_{SS}$  is the SS/TR source current, see the [Electrical Characteristics](#).
- $V_{REF}$  is the feedback regulation voltage divided by tracking gain ( $V_{FB} / 0.75$ ); see the [Electrical Characteristics](#).

The fastest achievable typical ramp time is 150  $\mu$ s, even if the external  $C_{SS}$  capacitance is lower than 680 pF or the pin is open.

## 9.2.3 Application Curves

### 9.2.3.1 Application Curves $V_{OUT} = 1.8\text{ V}$

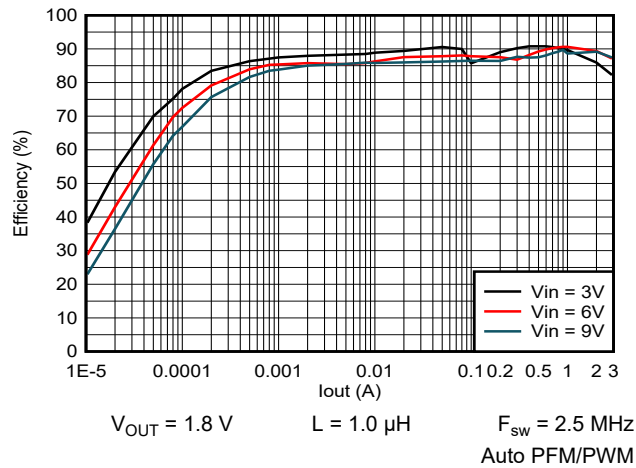


Figure 9-3. Efficiency vs Output Current

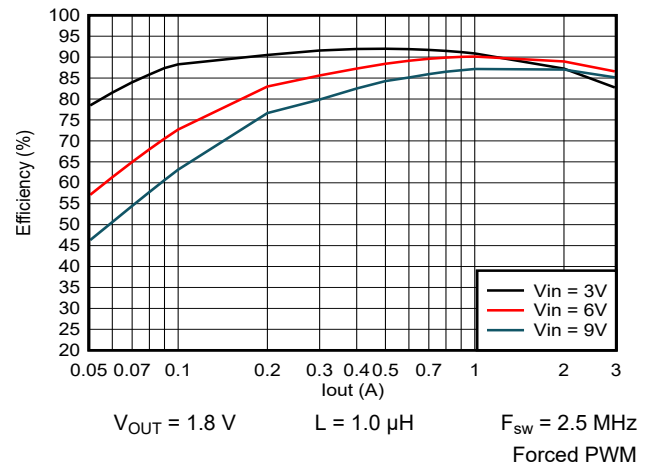


Figure 9-4. Efficiency vs Output Current

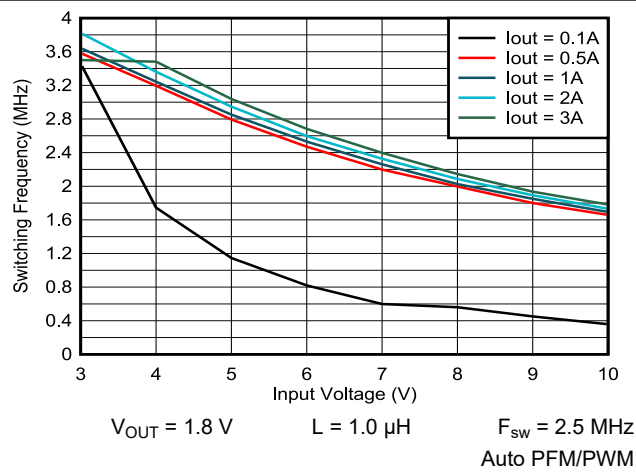


Figure 9-5. Switching Frequency vs Input Voltage

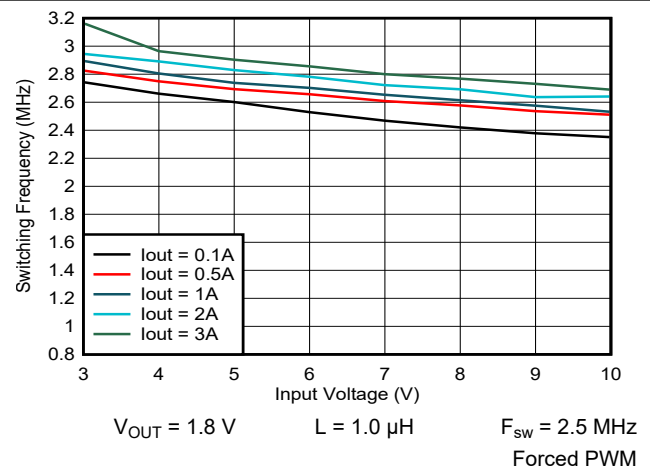


Figure 9-6. Switching Frequency vs Input Voltage

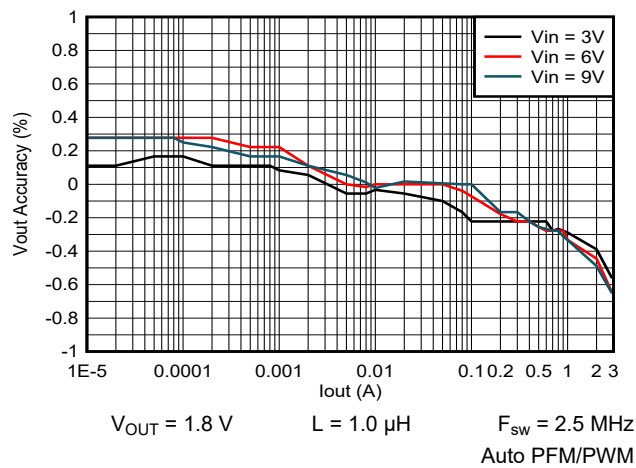


Figure 9-7. Output Voltage vs Output Current

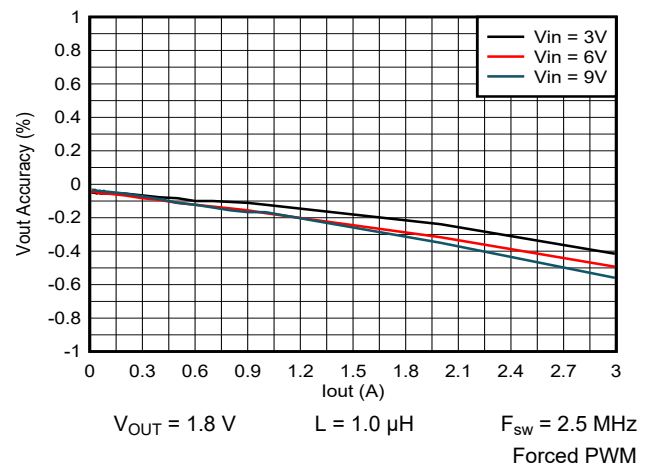


Figure 9-8. Output Voltage vs Output Current

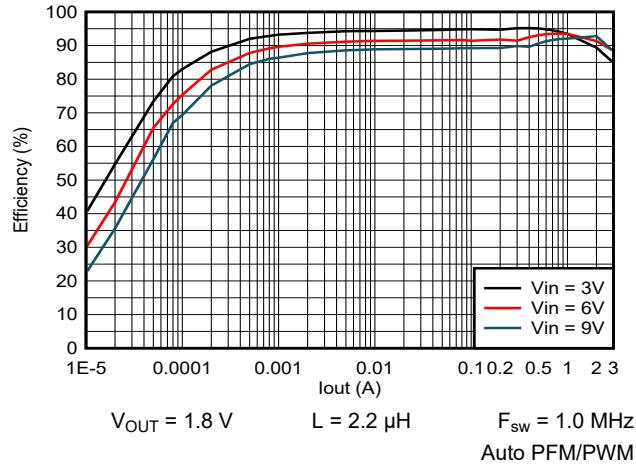


Figure 9-9. Efficiency vs Output Current

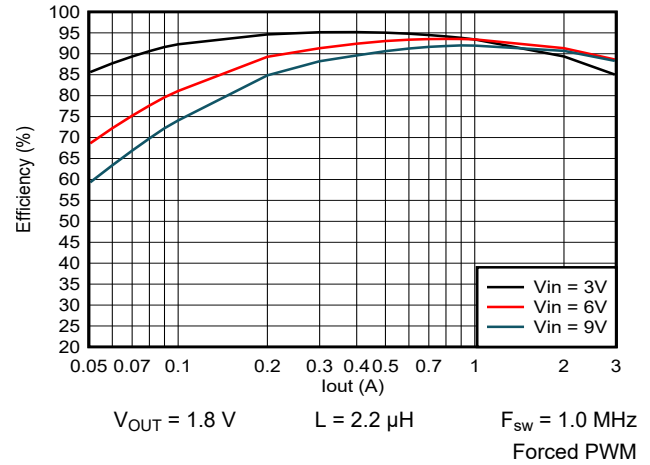


Figure 9-10. Efficiency vs Output Current

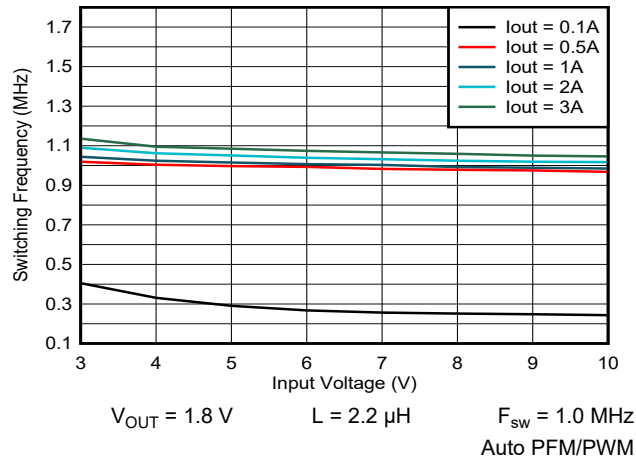


Figure 9-11. Switching Frequency vs Input Voltage

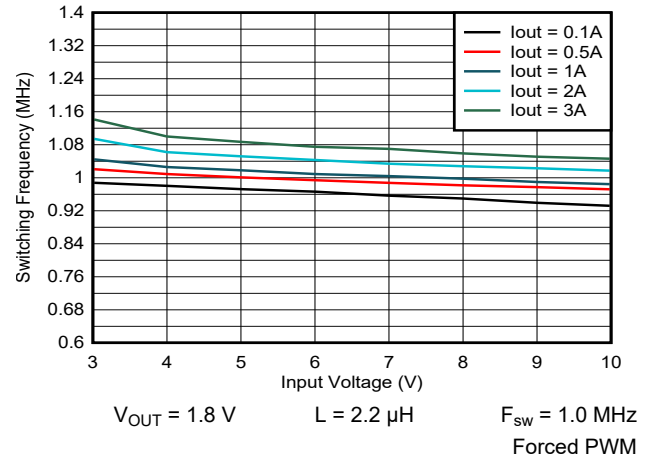


Figure 9-12. Switching Frequency vs Input Voltage

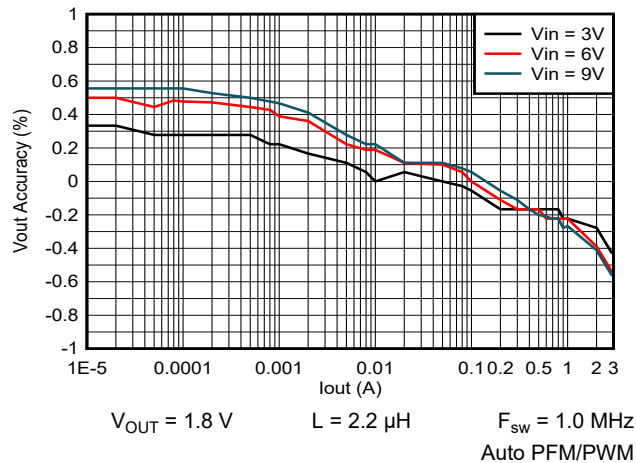


Figure 9-13. Output Voltage vs Output Current

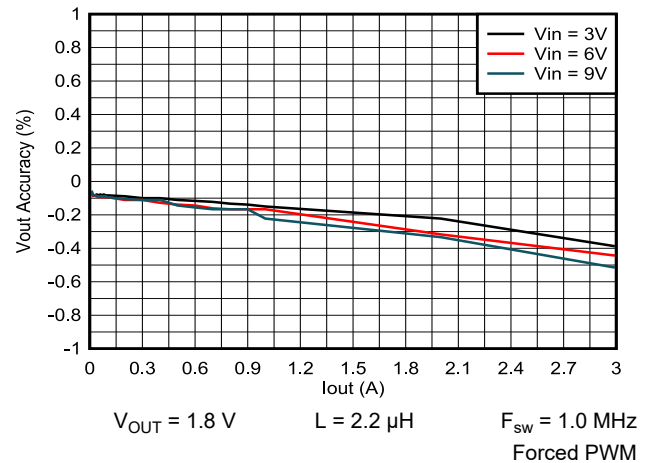
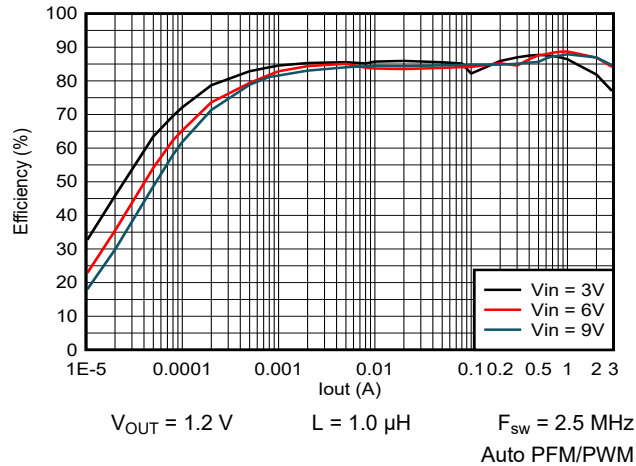
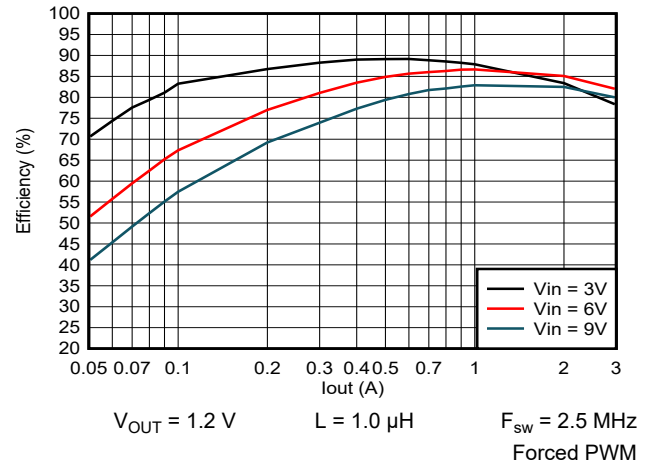


Figure 9-14. Output Voltage vs Output Current

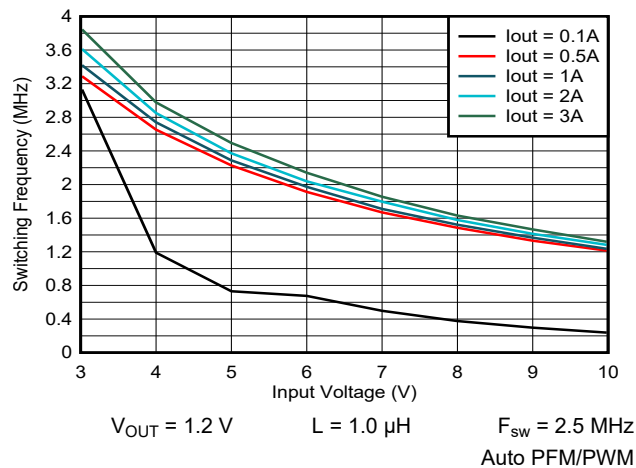
### 9.2.3.2 Application Curves $V_{OUT} = 1.2\text{ V}$



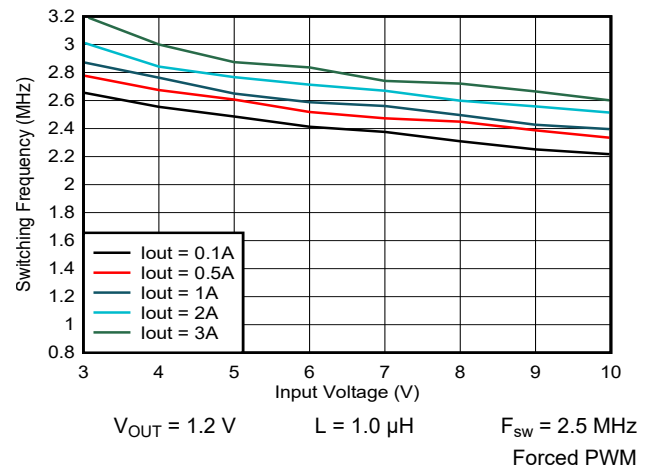
9-15. Efficiency vs Output Current



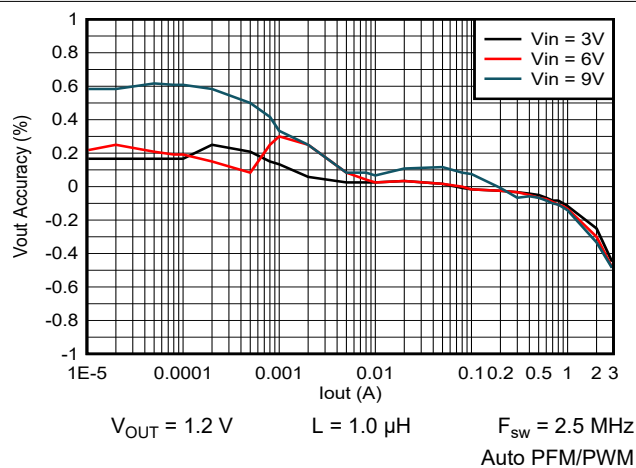
9-16. Efficiency vs Output Current



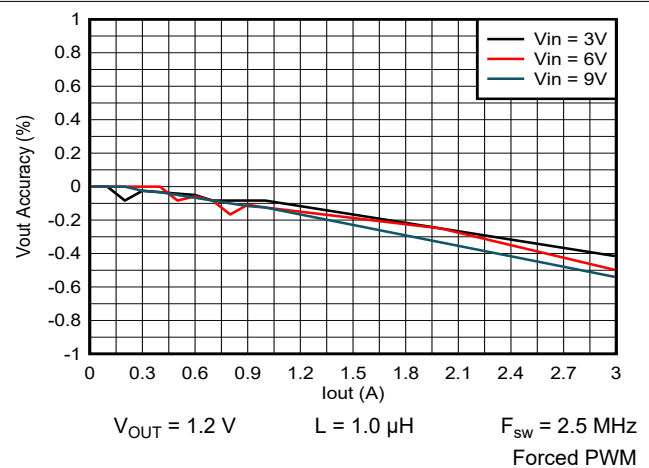
9-17. Switching Frequency vs Input Voltage



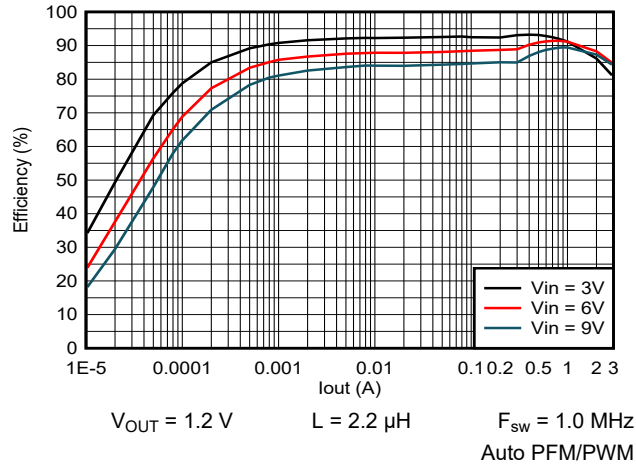
9-18. Switching Frequency vs Input Voltage



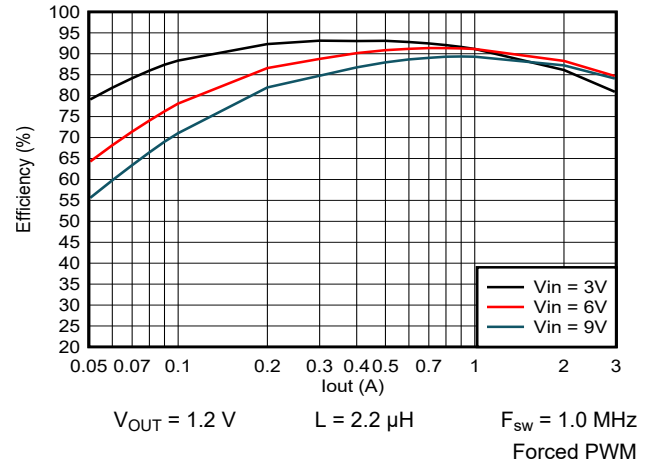
9-19. Output Voltage vs Output Current



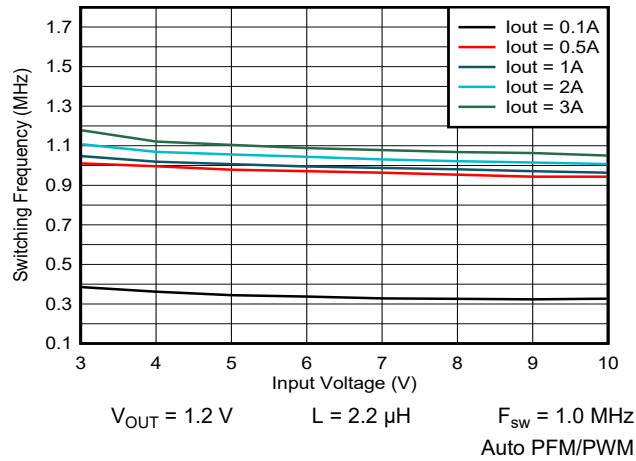
9-20. Output Voltage vs Output Current



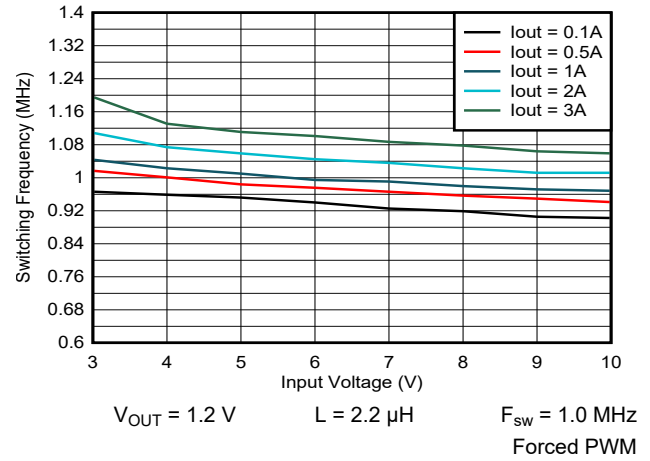
9-21. Efficiency vs Output Current



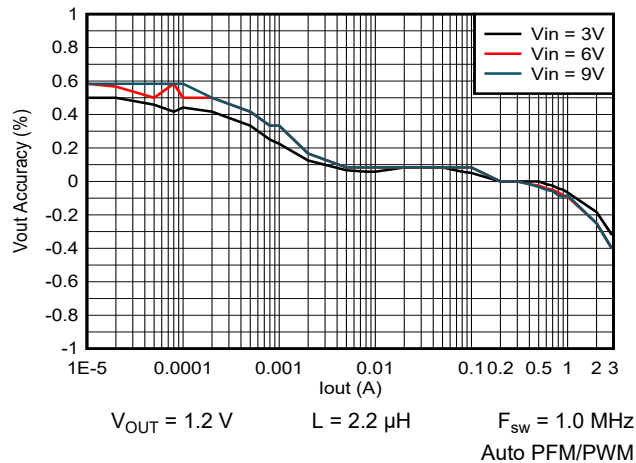
9-22. Efficiency vs Output Current



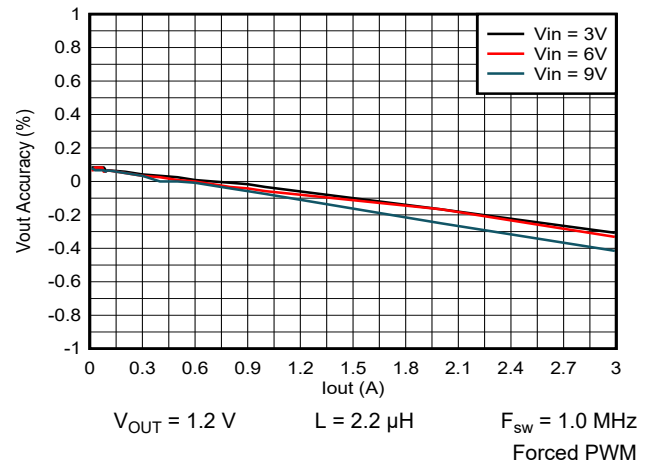
9-23. Switching Frequency vs Input Voltage



9-24. Switching Frequency vs Input Voltage

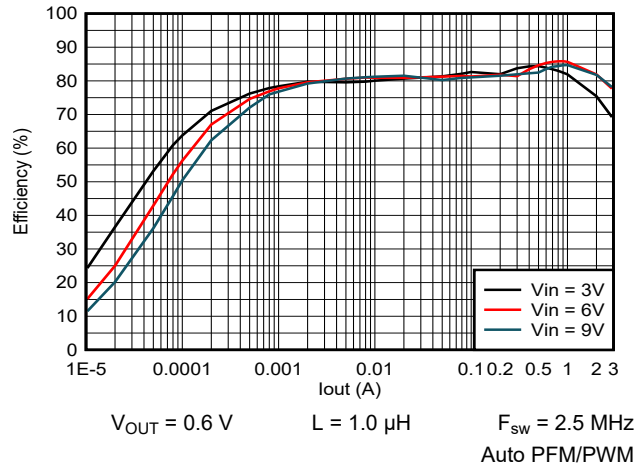


9-25. Output Voltage vs Output Current

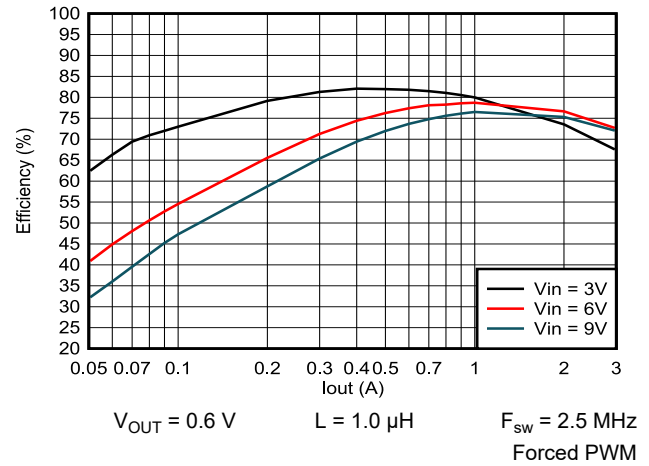


9-26. Output Voltage vs Output Current

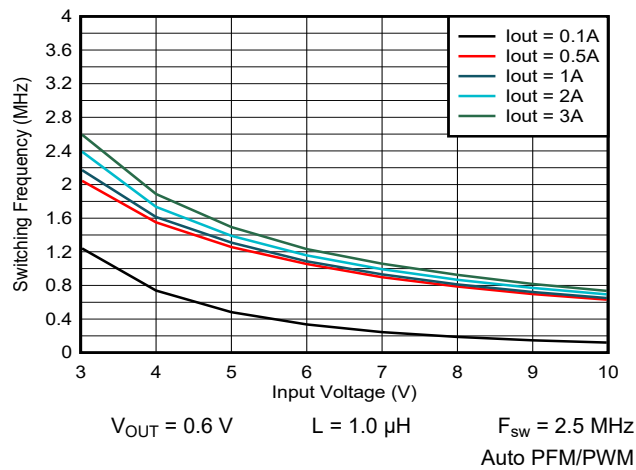
### 9.2.3.3 Application Curves $V_{OUT} = 0.6\text{ V}$



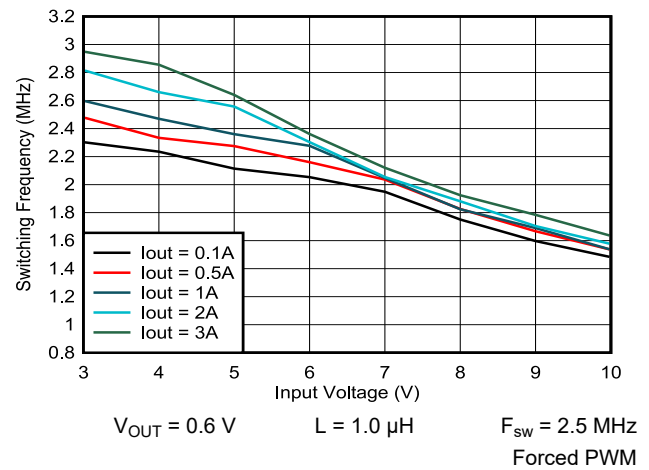
**9-27. Efficiency vs Output Current**



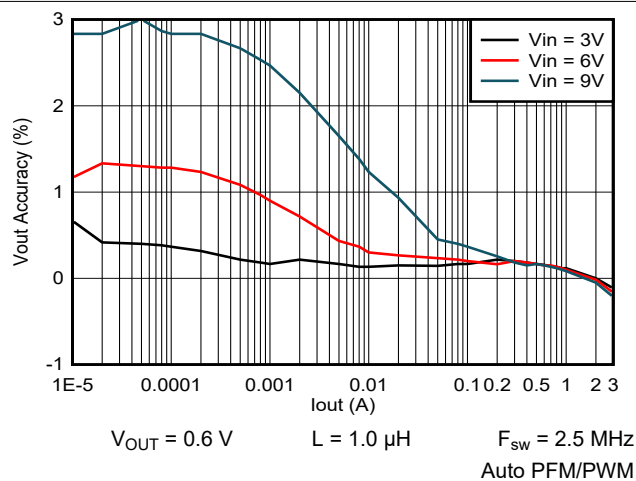
**9-28. Efficiency vs Output Current**



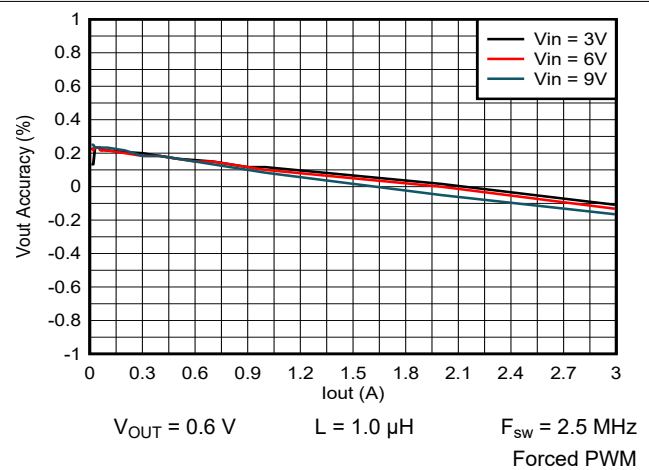
**9-29. Switching Frequency vs Input Voltage**



**9-30. Switching Frequency vs Input Voltage**

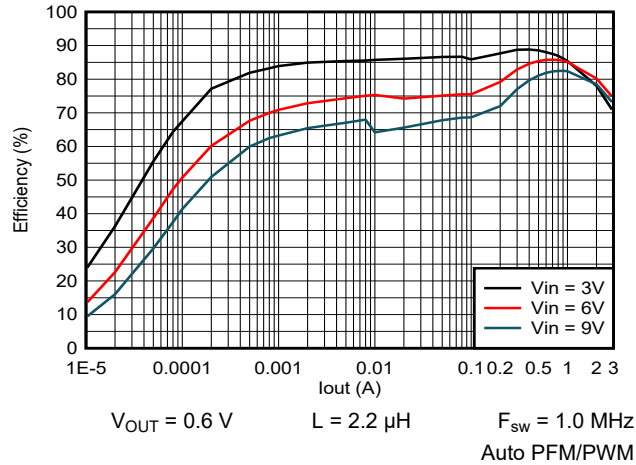


**9-31. Output Voltage vs Output Current**

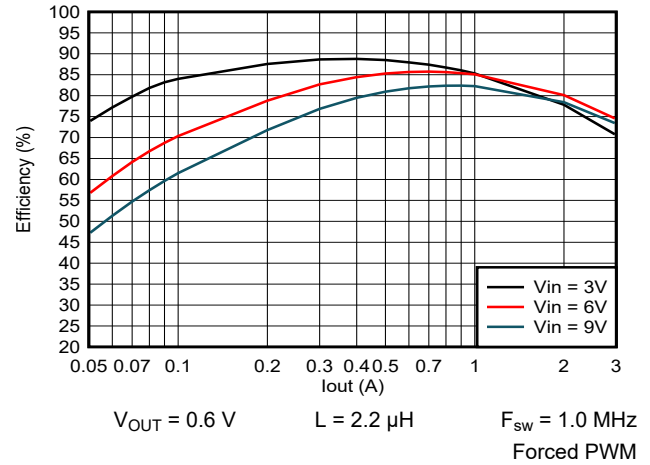


**9-32. Output Voltage vs Output Current**

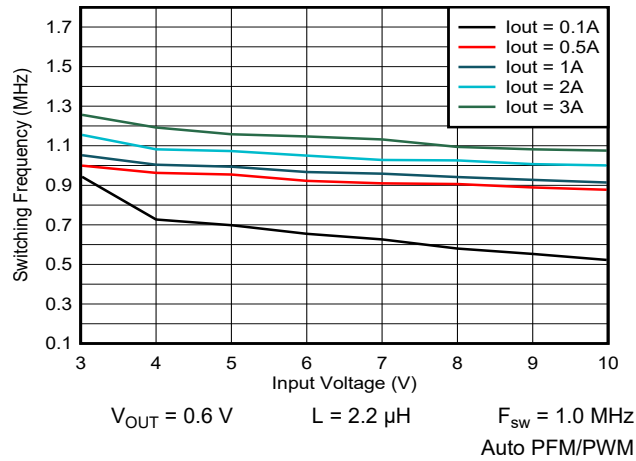




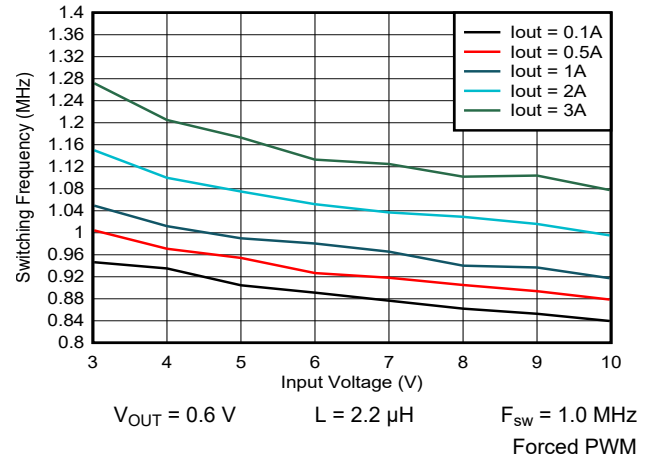
9-33. Efficiency vs Output Current



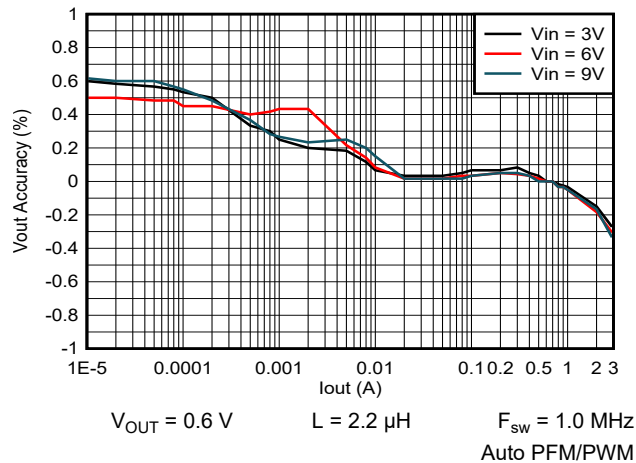
9-34. Efficiency vs Output Current



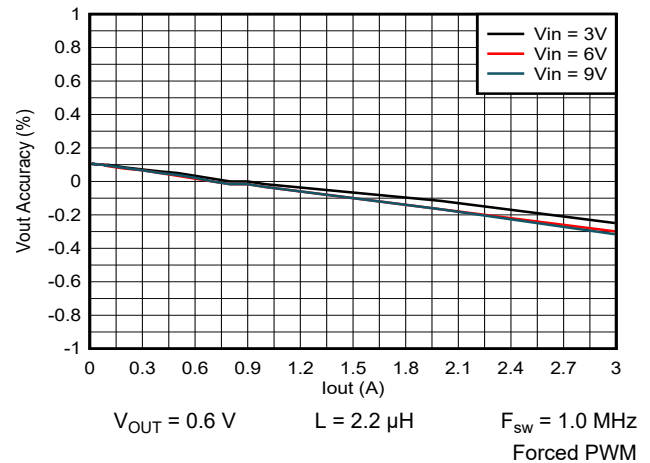
9-35. Switching Frequency vs Input Voltage



9-36. Switching Frequency vs Input Voltage



9-37. Output Voltage vs Output Current



9-38. Output Voltage vs Output Current

### 9.3 Typical Application with Selectable $V_{OUT}$ using VSET

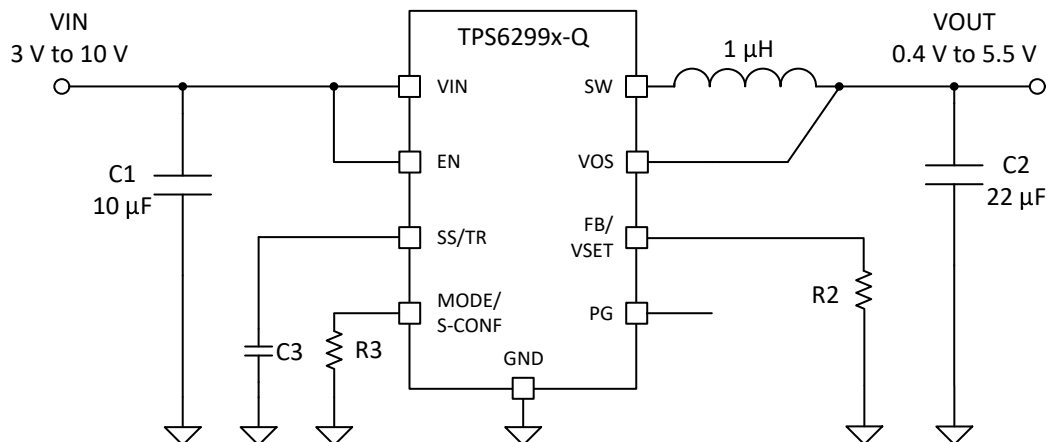


図 9-39. Typical Application Circuit (VSET)

#### 9.3.1 Design Requirements

表 9-6. List of Components

| Reference | Description                                                         | Manufacturer                               |
|-----------|---------------------------------------------------------------------|--------------------------------------------|
| IC        | 10 V, 3-A step-down converter                                       | TPS62993-Q1 series; Texas Instruments      |
| L         | 1-µH inductor                                                       | XGL4020-102; Coilcraft                     |
| CIN       | 10 µF, 25 V, Ceramic, X8R                                           | CGA6P1X8R1E106K250AE, TDK                  |
| COUT      | 22 µF, 16 V, Ceramic, X8L                                           | CGA6P1X8L1C226M250AC, TDK                  |
| CSS       | Depends on soft-start time; see <a href="#">セクション 9.2.2.3.3.3</a> . | AEC-Q200 qualified, 16 V, Ceramic, X8R     |
| R2        | Depending on $V_{OUT}$ ; see <a href="#">セクション 8.3.3</a>            | AEC-Q200 qualified, Standard 1% metal film |
| R3        | Depending on device setting, see <a href="#">セクション 8.3.1</a> .      | AEC-Q200 qualified, Standard 1% metal film |

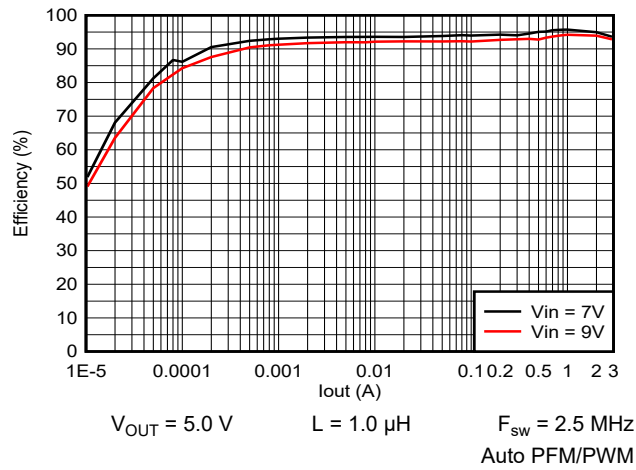
#### 9.3.2 Detailed Design Procedure

##### 9.3.2.1 Programming the Output Voltage

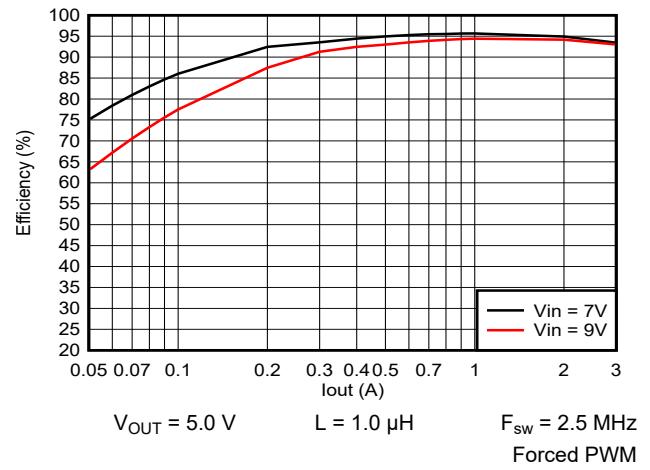
When the resistor (R3) on the MODE/S-CONF pin is sized for "VSET" (internal FB) operation (see [表 8-1](#)), the output voltage of the TPS62993-Q1 becomes selectable with a resistor (R2) from the FB/VSET pin to the GND. The output can be programmed to one of 16 different fixed output voltages ranging from 0.4 V to 5.5 V based on [表 8-2](#).

### 9.3.3 Application Curves

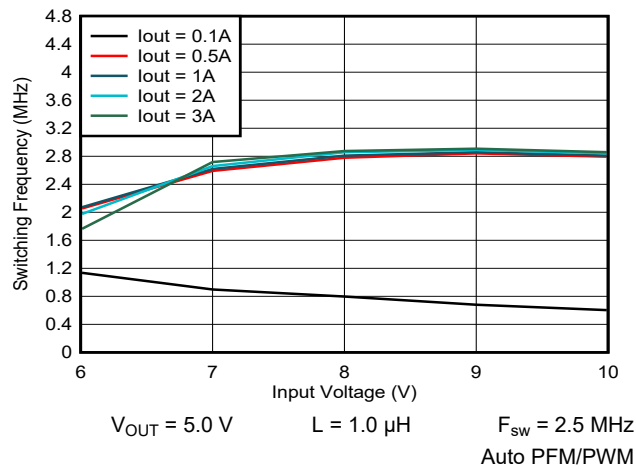
#### 9.3.3.1 Application Curves $V_{OUT} = 5\text{ V}$



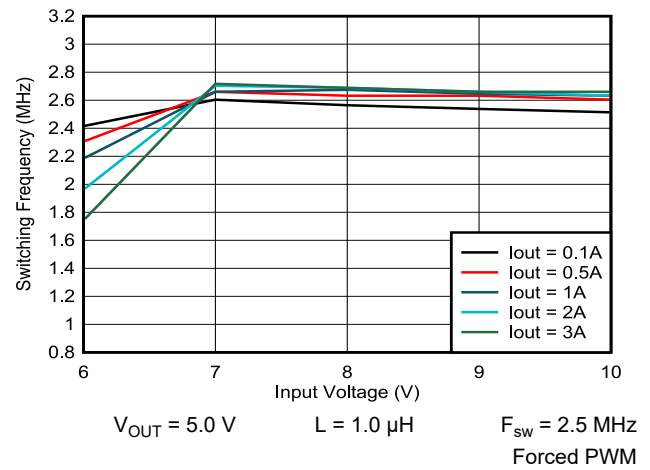
9-40. Efficiency vs Output Current



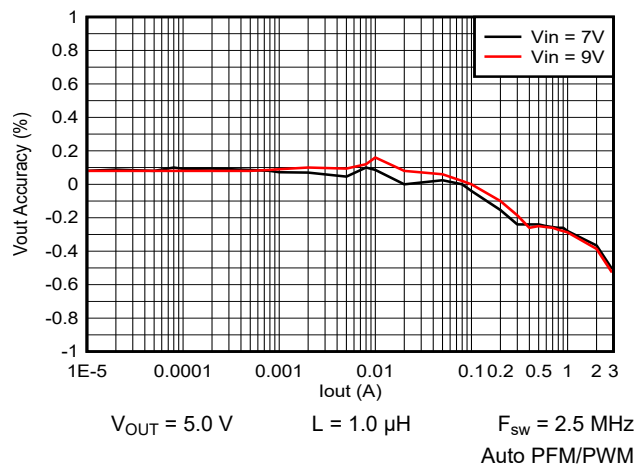
9-41. Efficiency vs Output Current



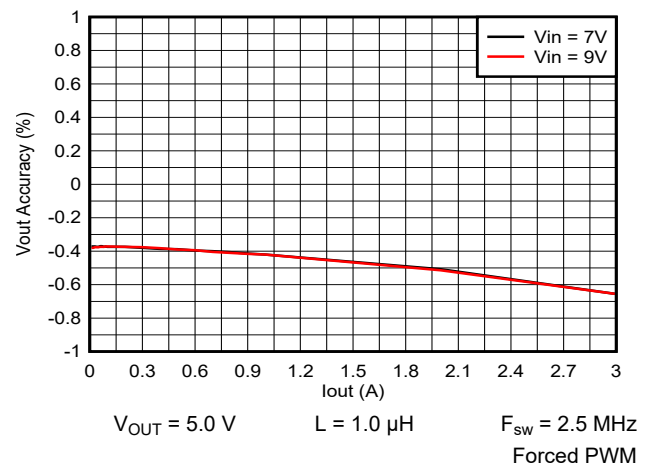
9-42. Switching Frequency vs Input Voltage



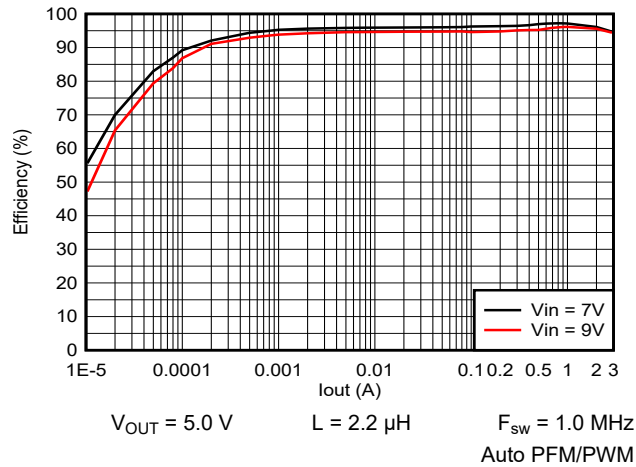
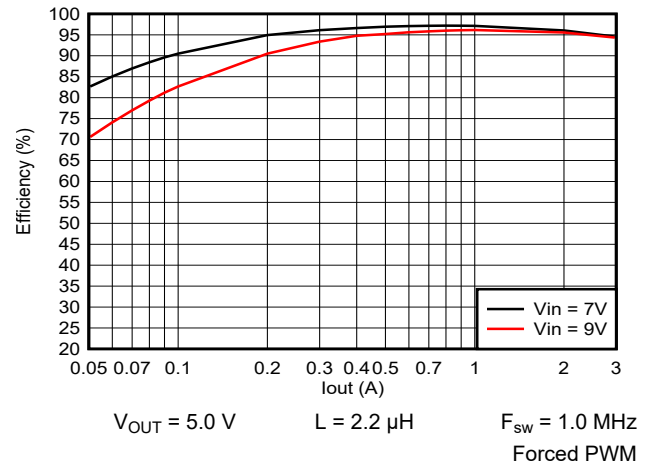
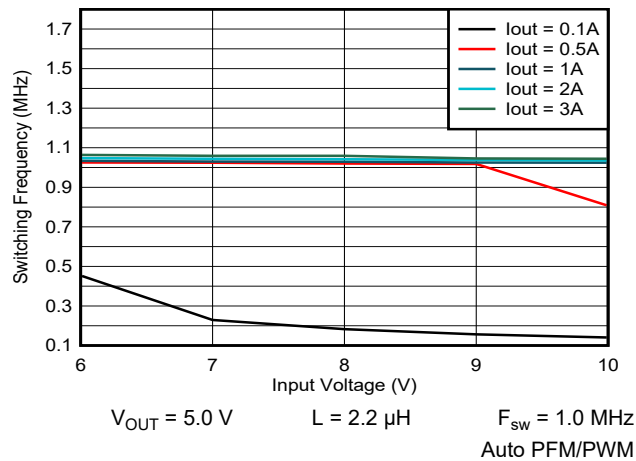
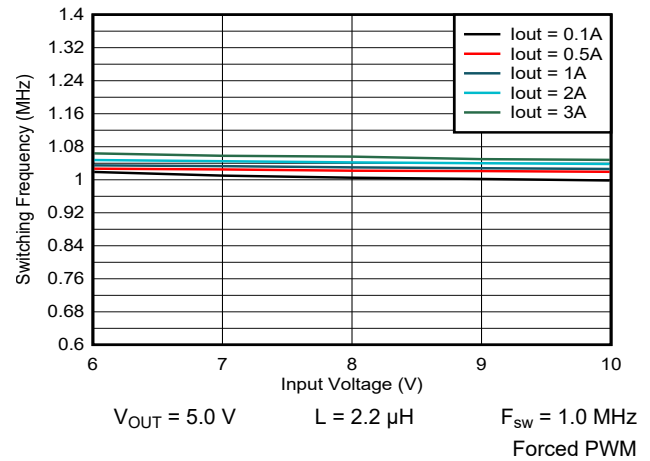
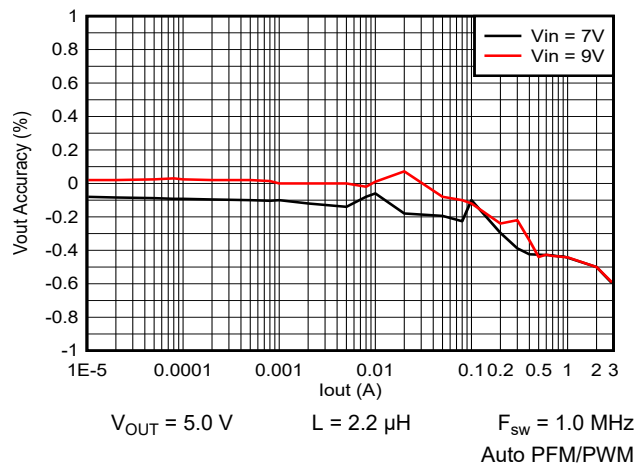
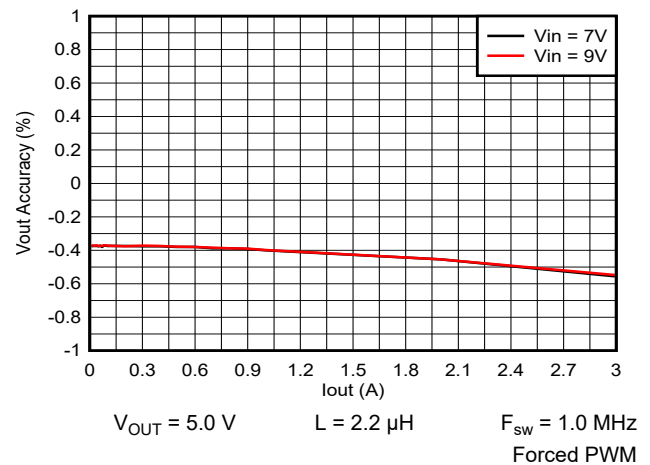
9-43. Switching Frequency vs Input Voltage



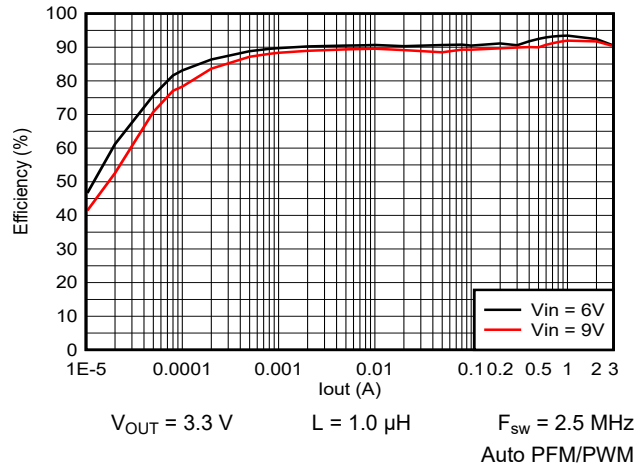
9-44. Output Voltage vs Output Current



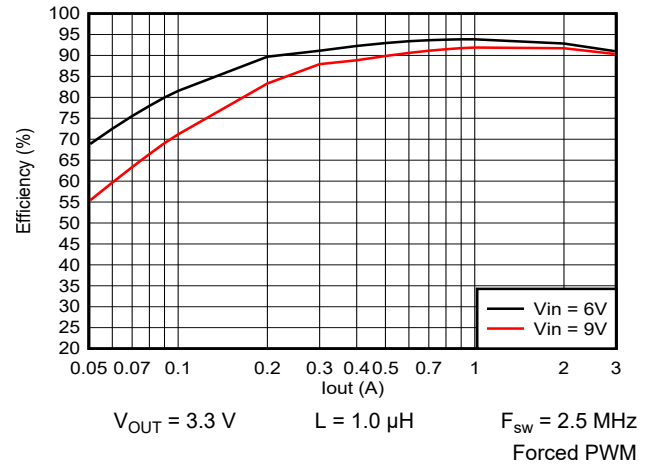
9-45. Output Voltage vs Output Current


 **9-46. Efficiency vs Output Current**

 **9-47. Efficiency vs Output Current**

 **9-48. Switching Frequency vs Input Voltage**

 **9-49. Switching Frequency vs Input Voltage**

 **9-50. Output Voltage vs Output Current**

 **9-51. Output Voltage vs Output Current**

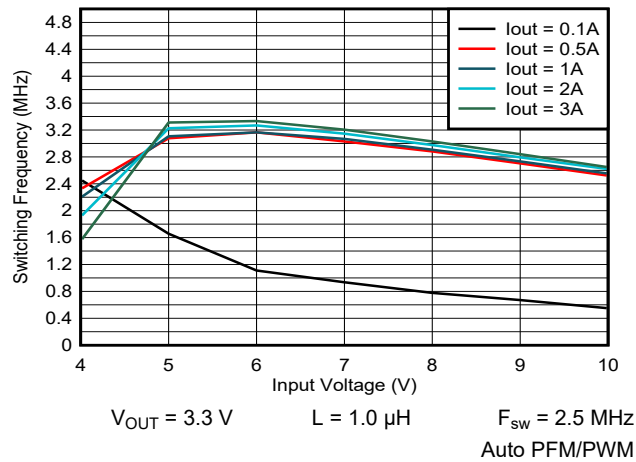
### 9.3.3.2 Application Curves $V_{OUT} = 3.3\text{ V}$



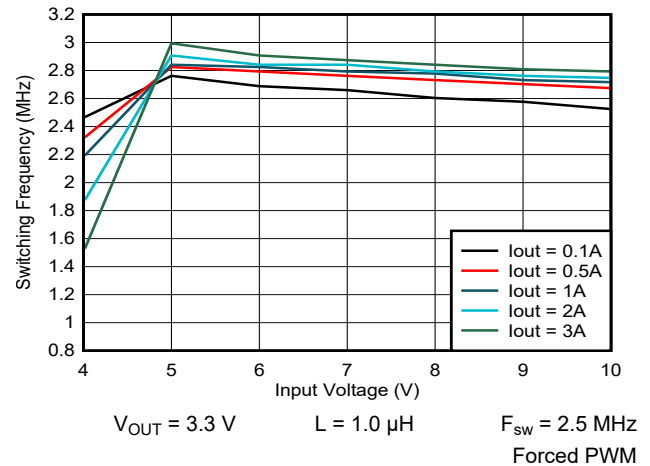
9-52. Efficiency vs Output Current



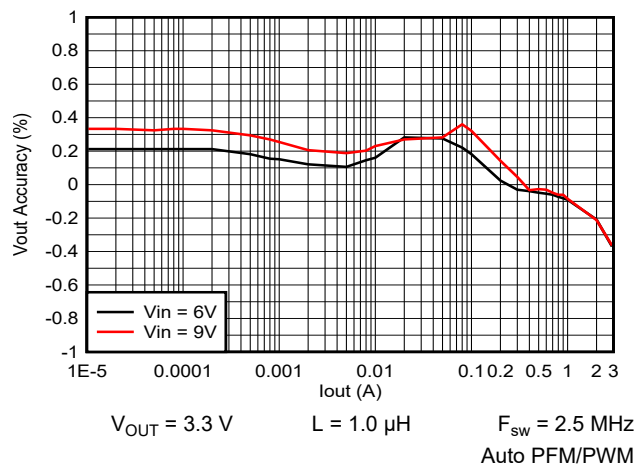
9-53. Efficiency vs Output Current



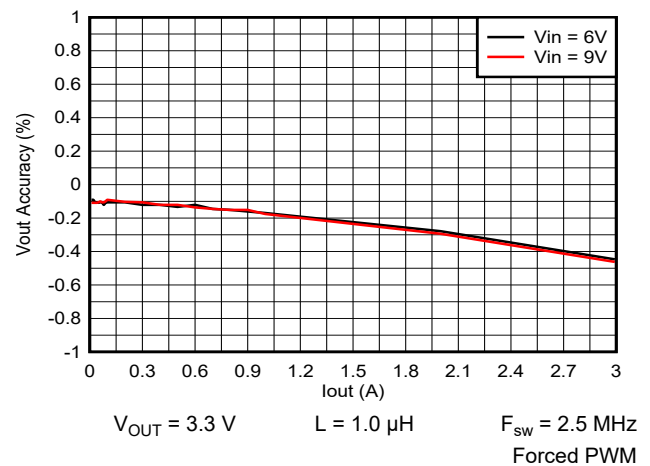
9-54. Switching Frequency vs Input Voltage



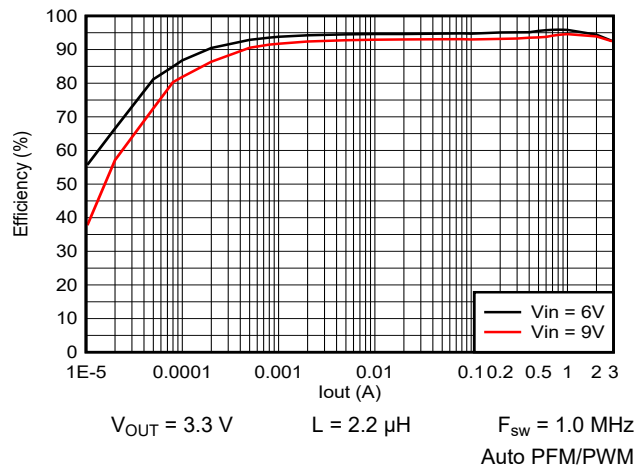
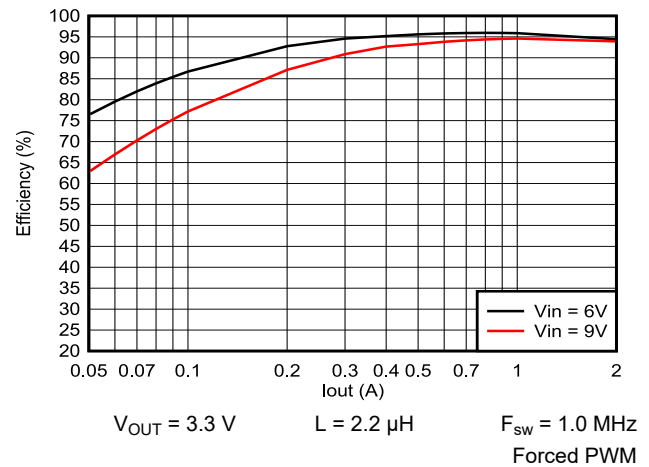
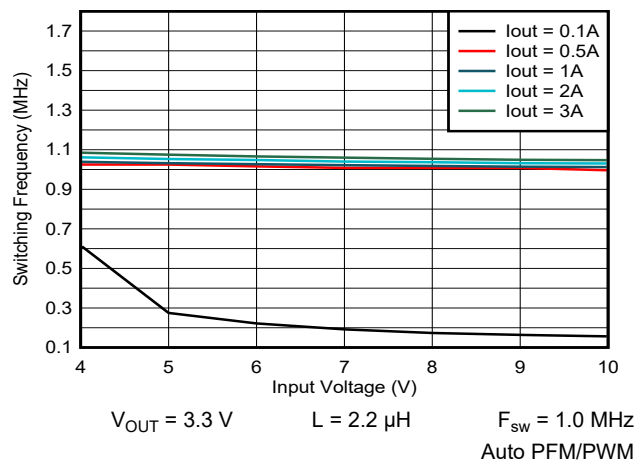
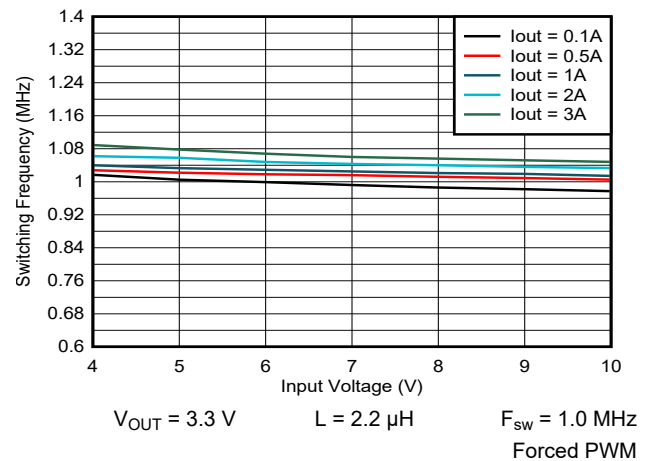
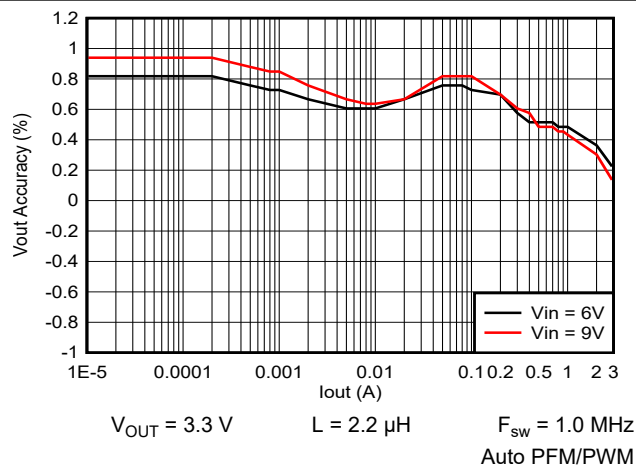
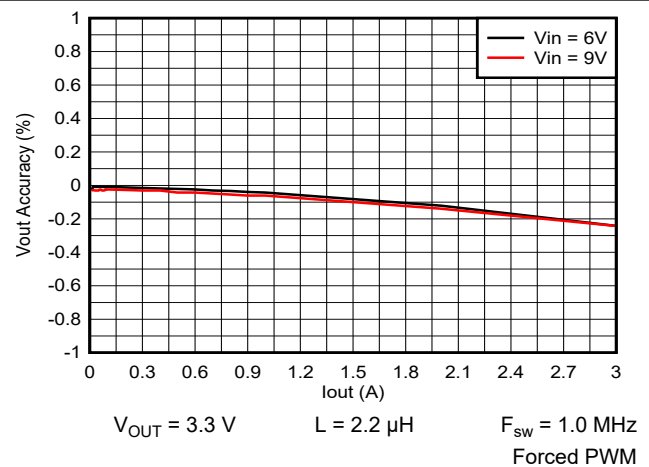
9-55. Switching Frequency vs Input Voltage

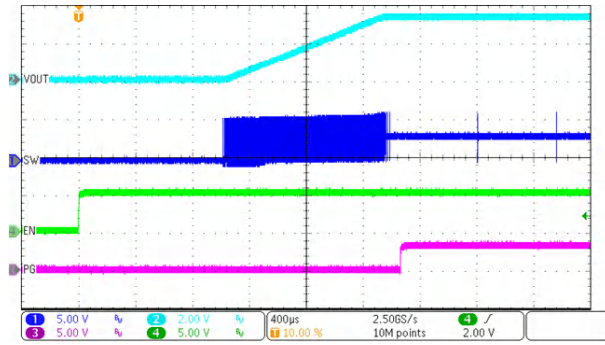


9-56. Output Voltage vs Output Current



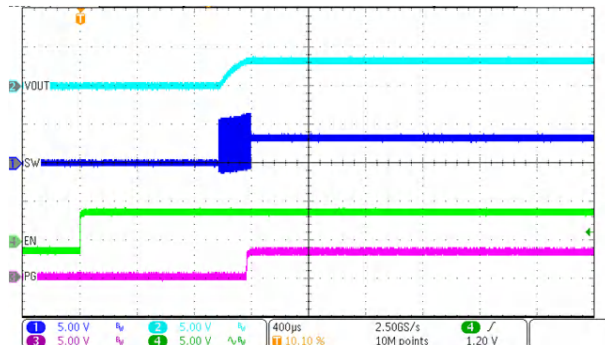
9-57. Output Voltage vs Output Current


 **9-58. Efficiency vs Output Current**

 **9-59. Efficiency vs Output Current**

 **9-60. Switching Frequency vs Input Voltage**

 **9-61. Switching Frequency vs Input Voltage**

 **9-62. Output Voltage vs Output Current**

 **9-63. Output Voltage vs Output Current**



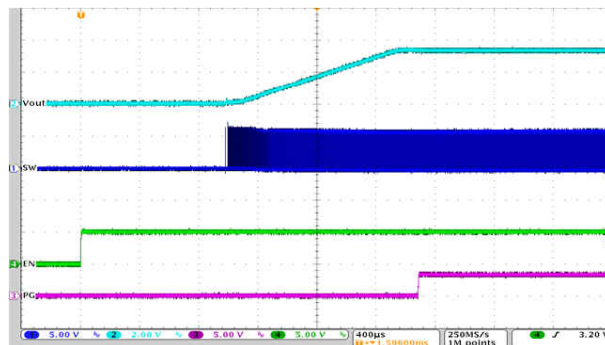
$V_{IN} = 6\text{ V}$   $C_{SS} = 3.3\text{ nF}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 0\text{ A}$  Auto PFM/PWM

图 9-64. Start-Up Timing



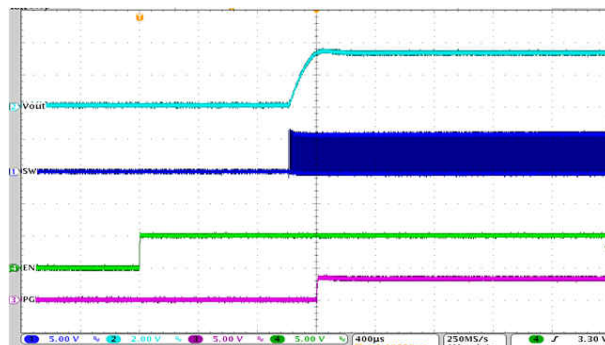
$V_{IN} = 6\text{ V}$   $C_{SS} = 0\text{ nF}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 0\text{ A}$  Auto PFM/PWM

图 9-65. Start-Up Timing



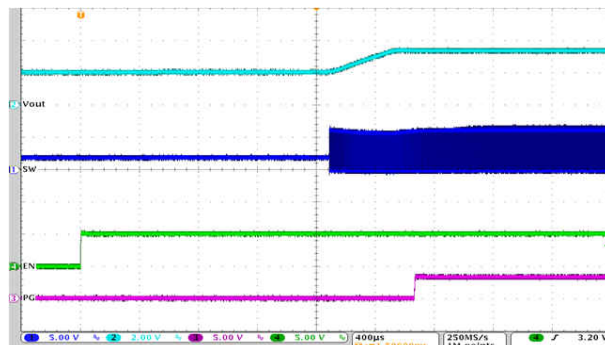
$V_{IN} = 6\text{ V}$   $C_{SS} = 3.3\text{ nF}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

图 9-66. Start-Up Timing



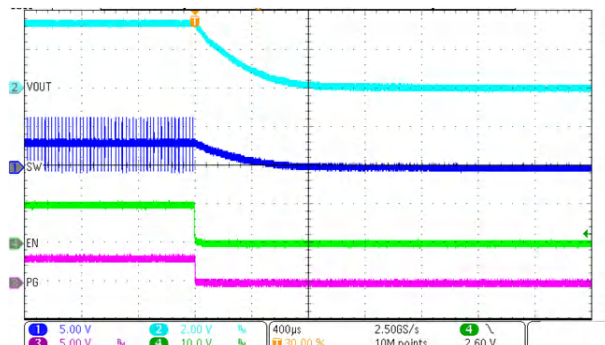
$V_{IN} = 6\text{ V}$   $C_{SS} = 0\text{ nF}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

图 9-67. Start-Up Timing



$V_{IN} = 6\text{ V}$   $C_{SS} = 3.3\text{ nF}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 0\text{ A}$  FPWM

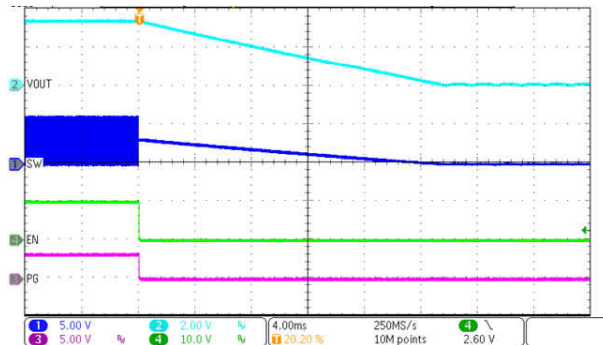
图 9-68. Start-Up into Prebiased Output



$V_{IN} = 6\text{ V}$   $L = 1.0\text{ µH}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 10\text{ mA}$  Auto PFM/PWM

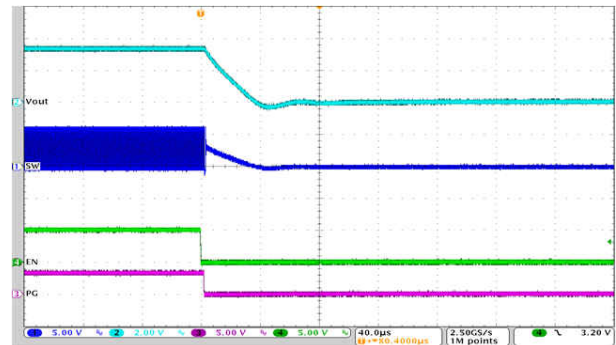
图 9-69. Shutdown Timing with Output Discharge Enabled





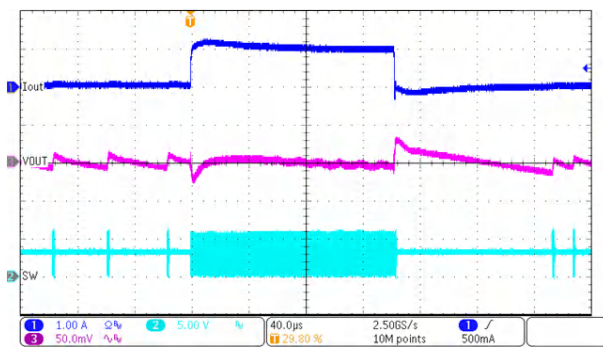
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 10\text{ mA}$  Auto PFM/PWM

**图 9-70. Shutdown Timing with Output Discharge Disabled**



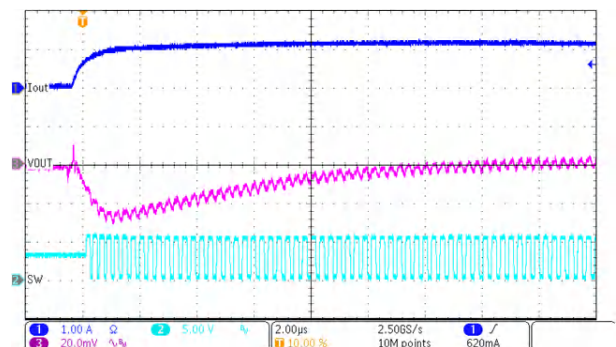
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

**图 9-71. Shutdown Timing with Output Discharge Disabled**



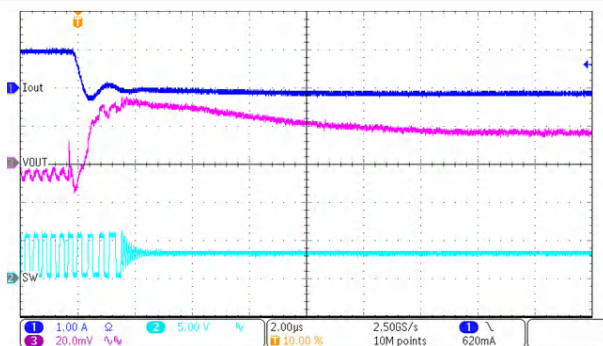
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 10\text{ mA to }1\text{ A}$  Auto PFM/PWM

**图 9-72. Load Transient Response**



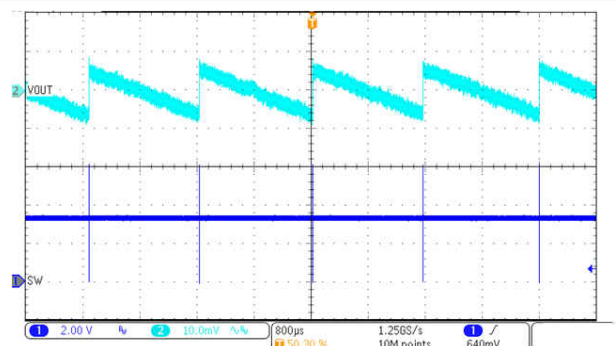
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 10\text{ mA to }1\text{ A}$  Auto PFM/PWM

**图 9-73. Load Transient Response Undershoot**



$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 1\text{ A to }10\text{ mA}$  Auto PFM/PWM

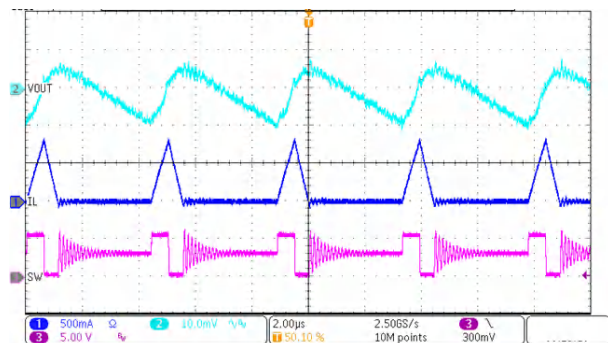
**图 9-74. Load Transient Response Overshoot**



$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 0\text{ A}$  Auto PFM/PWM

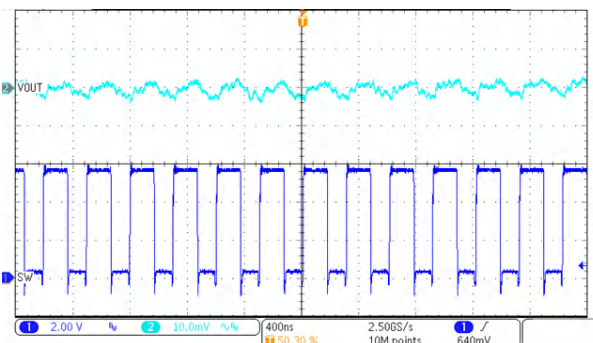
**图 9-75. Output Voltage Ripple**





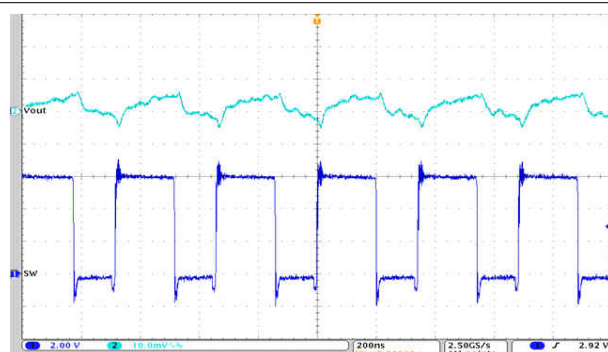
$V_{IN} = 6\text{ V}$   $L = 2.2\text{ }\mu\text{H}$   $F_{SW} = 1.0\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 100\text{ mA}$  Auto PFM/PWM

9-76. Output Voltage Ripple



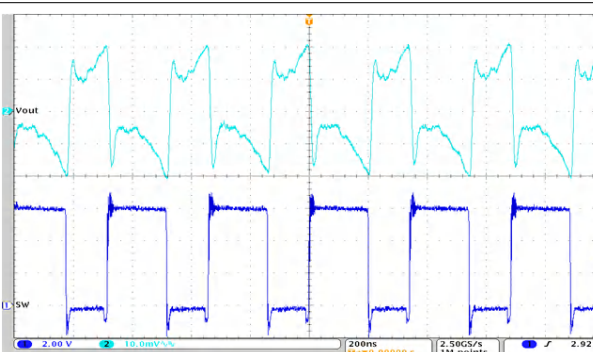
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 1\text{ A}$  Auto PFM/PWM

9-77. Output Voltage Ripple



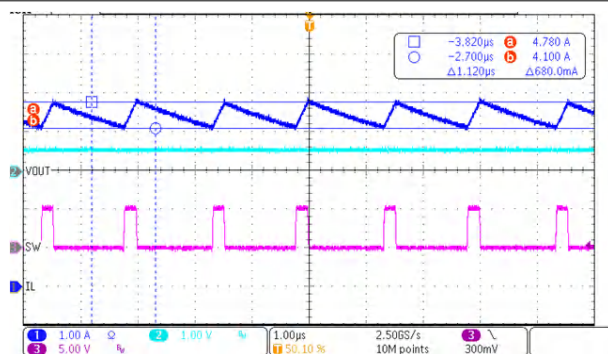
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

9-78. Output Voltage Ripple



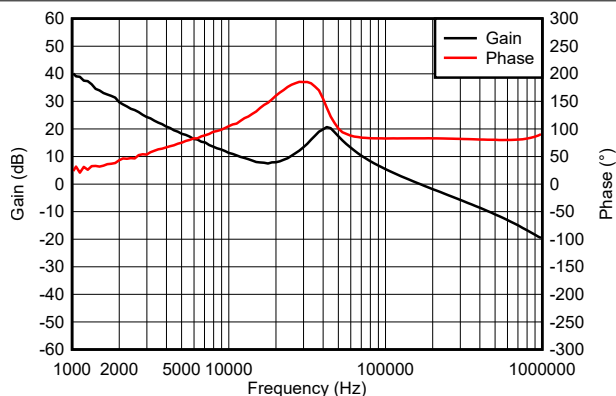
$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

9-79. Input Voltage Ripple



$V_{IN} = 6\text{ V}$   $L = 2.2\text{ }\mu\text{H}$   $F_{SW} = 1.0\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 5\text{ A}$  FPWM

9-80. Current Limit



$V_{IN} = 6\text{ V}$   $L = 1.0\text{ }\mu\text{H}$   $F_{SW} = 2.5\text{ MHz}$   
 $V_{OUT} = 3.3\text{ V}$   $I_{OUT} = 3\text{ A}$  FPWM

9-81. Bode Plot

## 9.4 System Examples

### 9.4.1 LED Power Supply

The TPS62993-Q1 can be used as a power supply for power LEDs. The FB pin can be easily set to lower values than nominal by using the SS/TR pin. With that, the voltage drop on the sense resistor (R2) is reduced to avoid excessive power loss. Because the SS/TR pin provides 2.5  $\mu\text{A}$  (typical), the feedback pin voltage can be adjusted by an external resistor per 式 19. This drop, proportional to the LED current, is used to regulate the output voltage (anode voltage) to a proper level to drive the LED. Both analog and PWM dimming are supported with the TPS62993-Q1. 図 9-82 shows an application circuit, tested with analog dimming.

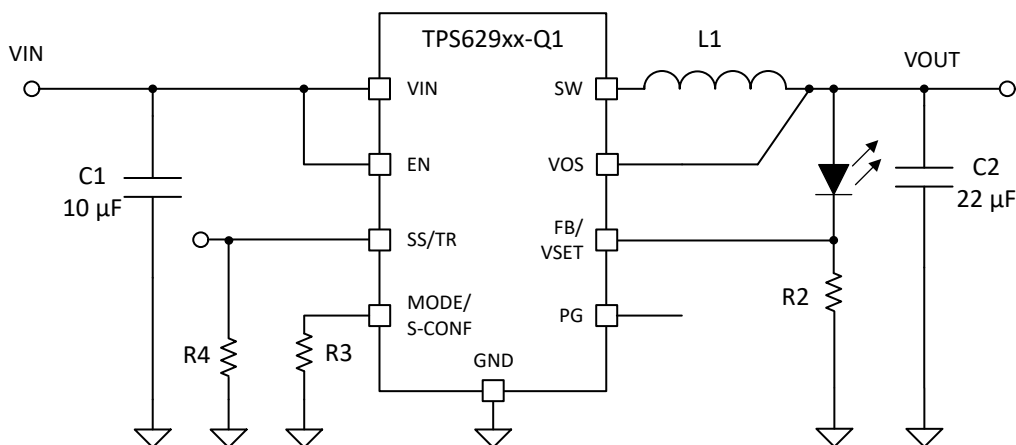


图 9-82. Single Power LED Supply

The resistor at SS/TR defines the FB voltage. The resistor at SS/TR is set to 304 mV by  $R_{SS/TR} = R4 = 162 \text{ k}\Omega$  using 式 19. This cuts the losses on R2 to half from the nominal 0.6 V of feedback voltage while it still provides good accuracy.

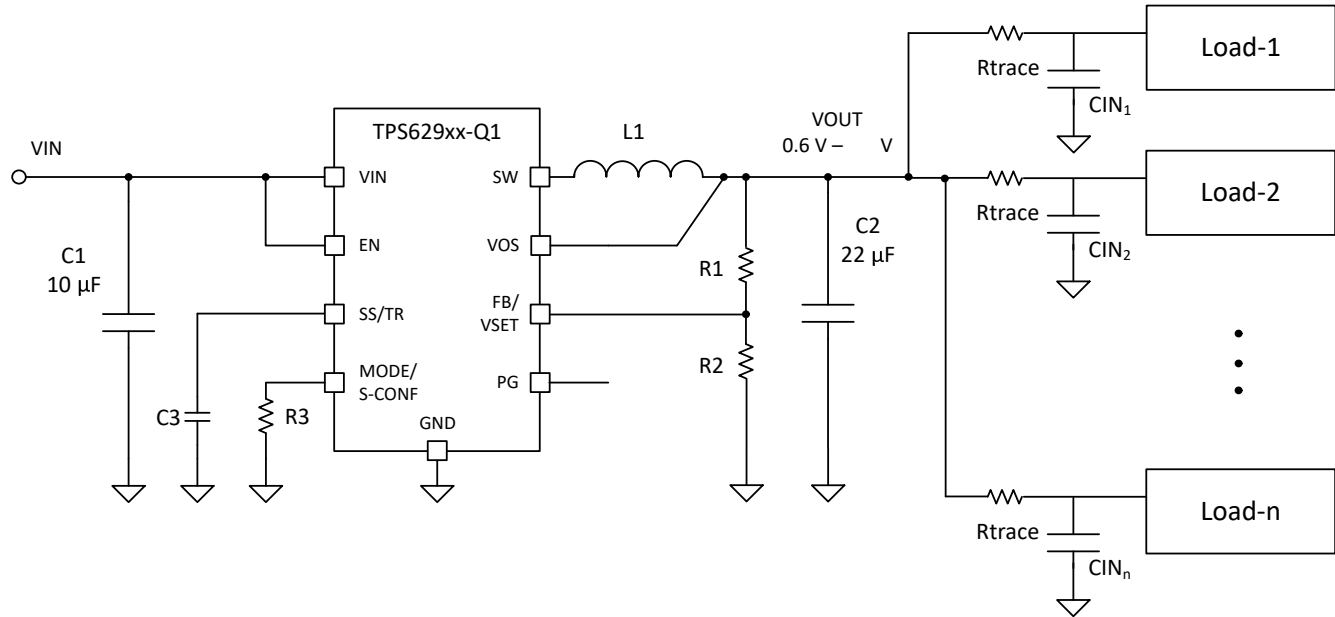
$$V_{FB} = 0.75 \times 2.5\mu\text{A} \times R_{SS/TR} \quad (19)$$

The device now supplies a constant current set by resistor R2 from FB/VSET to GND. The minimum input voltage has to be rated according the forward voltage needed by the LED used. More information is available in the [Step-Down LED Driver With Dimming With the TPS621-Family and TPS821-Family](#) application report.

### 9.4.2 Powering Multiple Loads

In applications where the TPS62993-Q1 is used to power multiple load circuits, the total capacitance on the output can be very large. To properly regulate the output voltage, there must be an appropriate AC signal level on the VOS pin. Tantalum capacitors have a large enough ESR to keep output voltage ripple sufficiently high on the VOS pin. With low-ESR ceramic capacitors, the output voltage ripple can get very low, so TI does not recommend to use a large capacitance directly on the output of the device. If there are several load circuits with their associated input capacitor on a PCB, these loads are typically distributed across the board. This adds enough trace resistance ( $R_{\text{trace}}$ ) to keep a large enough AC signal on the VOS pin for proper regulation.

The minimum total trace resistance on the distributed load is 10 m $\Omega$ . The total capacitance  $n \times C_{\text{IN}}$  in the use case below was  $32 \times 47 \mu\text{F}$  of ceramic X7R capacitors.



**9-83. Multiple Loads**

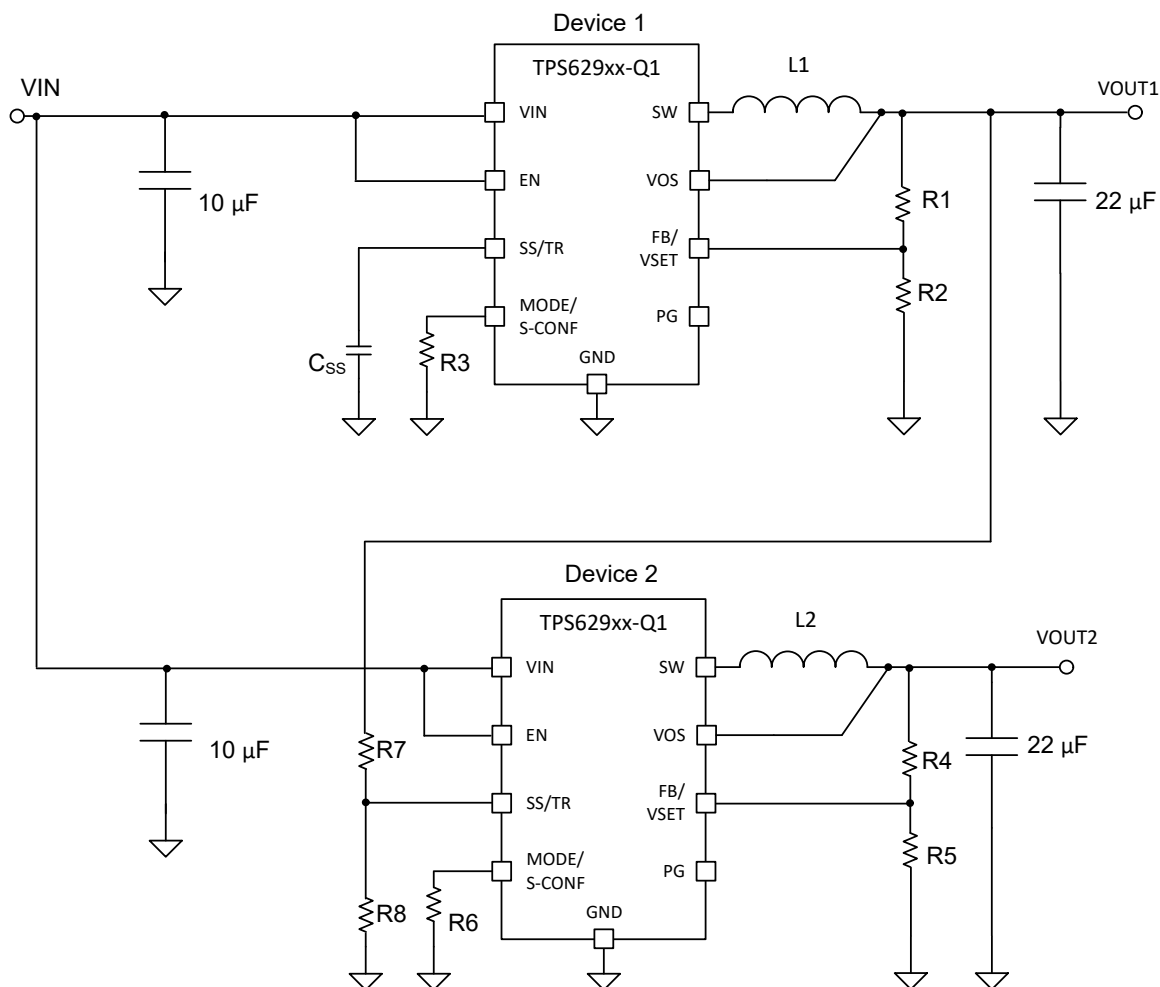
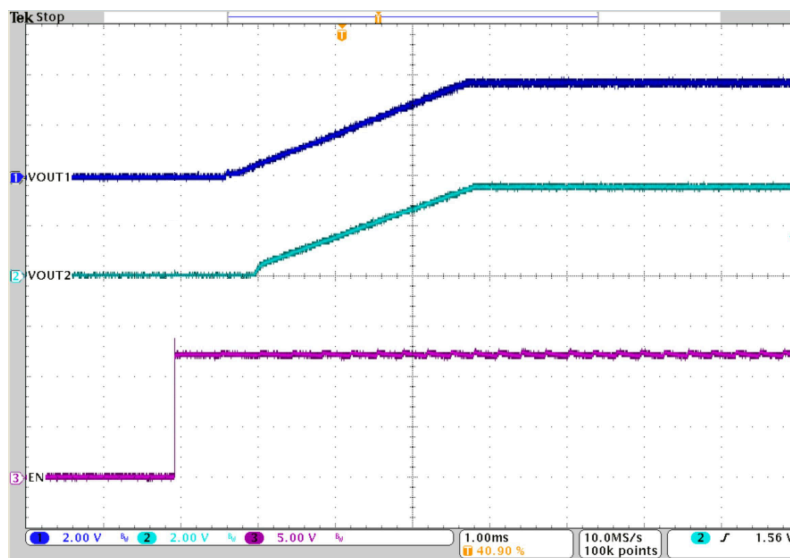
注

9-83 shows an external feedback configuration, but the internal (VSET) configuration can also be used.

### 9.4.3 Voltage Tracking

9-84 shows how two TPS62993-Q1s can be configured to tracking output voltages. In this configuration, Device 2 follows the voltage applied to its SS/TR pin from Device 1 output. A ramp on the SS/TR pin of Device 2 to 0.8 V in turn ramps VOUT2 according to the 0.6-V reference on  $V_{FB}$  and the R4//R5 resistor divider.

For this example, to track the 3.8 V (VOUT1) of Device 1 a resistor divider (R7//R8) on SS/TR of Device 2 is required to generate 0.8 V when the output voltage (VOUT1) is in regulation. Due to the  $I_{SS}$  current of 2.5  $\mu$ A from the SS/TR pin, the equivalent resistance of R7 // R8 must be kept below 15 k $\Omega$  to minimize any offset the  $I_{SS}$  current can cause on the SS/TR pin voltage.


 **9-84. Tracking Example**

 **9-85. Tracking**

#### 9.4.4 Inverting Buck-Boost (IBB)

The need to generate negative voltage rails for electronic designs is a common challenge. The wide 3-V to 10-V input voltage range of the TPS62993-Q1 makes it ideal for an inverting buck-boost (IBB) circuit, where the output voltage is inverted or negative with respect to ground.

The circuit operation in the IBB topology differs from that in the traditional buck topology. Though the components are connected the same as with a traditional buck converter, the output voltage terminals are reversed. See [Figure 9-86](#).

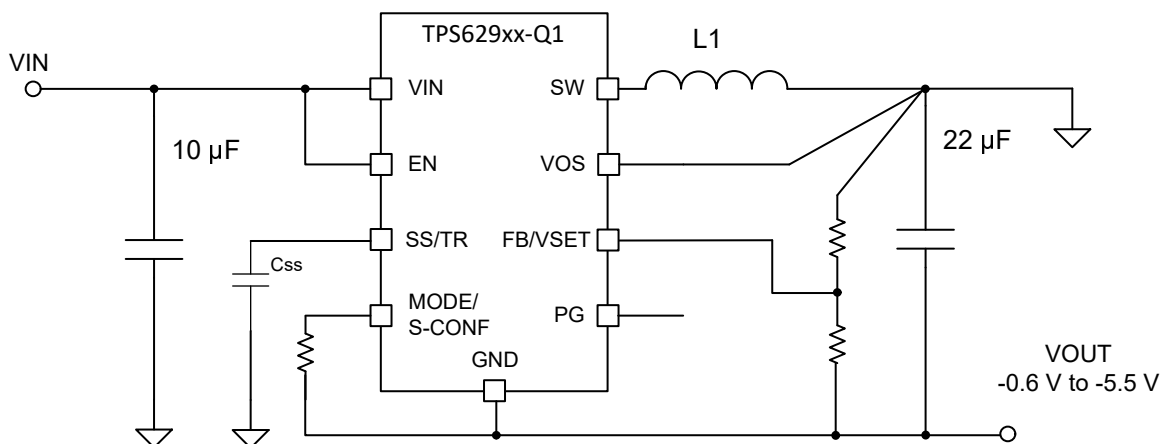
The maximum input voltage that can be applied to an IBB converter is less than the maximum voltage that can be applied to the TPS62993-Q1 in a typical buck configuration. This is because the ground pin of the IC is connected to the (negative) output voltage. Therefore, the input voltage across the device is  $V_{IN}$  to  $V_{OUT}$ , and not  $V_{IN}$  to ground. Thus, the input voltage range of the TPS62993-Q1 in an IBB configuration becomes 3 V to 10 V +  $V_{OUT}$ , where  $V_{OUT}$  is a negative value.

The output voltage range is the same as when configured as a buck converter, but only negative. Thus, the output voltage for a TPS62993-Q1 in an IBB configuration can be set between -0.4 V and -5.5 V.

The maximum output current for the TPS62993-Q1 in an IBB topology is normally lower than a traditional buck configuration due to the average inductor current being higher in an IBB configuration. Traditionally, lower input or (more negative) output voltages results in a lower maximum output current. However, using a larger inductor value or the higher 2.5-MHz frequency setting can be used to recover some or all of this lost maximum current capability.

When implementing an IBB design, it is important to understand that the IC ground is tied to the negative voltage rail, and in turn, the electrical characteristics of the TPS62993-Q1 device are referenced to this rail. During power up, as there is no charge in the output capacitor and the IC GND pin (and  $V_{OUT}$ ) are effectively 0 V, thus parameters such as the  $V_{IN}$  UVLO and EN thresholds are the same as in a typical buck configuration. However, after the output voltage is in regulation, due to the negative voltage on the IC GND pin, the device traditionally continues to operate below what can appear to be the normal UVLO or EN falling thresholds relative to the system ground. Take care if the user is using the dynamic mode change feature on the MODE pin of the TPS62993-Q1 or driving the EN pin from an upstream microcontroller as the high and low thresholds are relative to the negative rail and not the system ground.

More information on using a DCS regulator in an IBB configuration can be found in the [Description Compensating the Current Mode Boost Control Loop](#), [Using the TPS6215x in an Inverting Buck-Boost Topology](#), and [Using the TPS629210 in an Inverting Buck-Boost Topology](#) application notes.



**Figure 9-86. IBB Example with Adjustable Feedback**

注

図 9-86 shows an external feedback configuration, but the internal (VSET) configuration can also be used.

## 9.5 Power Supply Recommendations

The power supply to the TPS62993-Q1 must have a current rating according to the supply voltage, output voltage, and output current of the TPS62993-Q1. At a minimum, the input power supply must provide enough power to cover the maximum output power divided by the efficiency at maximum load. A good rule of thumb is to use a supply with an additional 50% of power capability to withstand the additional loading associated with power up, transient events, and potential overload events.

注

For current limited input supplies with a variable supply voltage, the minimum supply voltage must be used to determine if the power supply is sufficient.

## 9.6 Layout

### 9.6.1 Layout Guidelines

A proper layout is critical for the operation of a switched mode power supply, even more at high switching frequencies. Therefore, the PCB layout of the TPS62993-Q1 demands careful attention to make sure the device works correctly and to get the performance specified. A poor layout can lead to issues like poor regulation (both line and load), stability and accuracy weaknesses, increased EMI radiation, and noise sensitivity.

See 図 9-87 for the recommended layout of the TPS62993-Q1, which is designed for common external ground connections. The input capacitor must be placed as close as possible between the VIN and GND pin of TPS62993-Q1. Also, connect the VOS pin in the shortest way to VOUT at the output capacitor.

Provide low inductive and resistive paths for loops with high di/dt. Therefore paths, conducting the switched load current must be as short and wide as possible. Provide low capacitive paths (with respect to all other nodes) for traces with high dv/dt. Therefore, the input and output capacitance must be placed as close as possible to the IC pins and parallel wiring over long distances as well as narrow traces must be avoided. Loops that conduct an alternating current must outline an area as small as possible, as this area is proportional to the energy radiated.

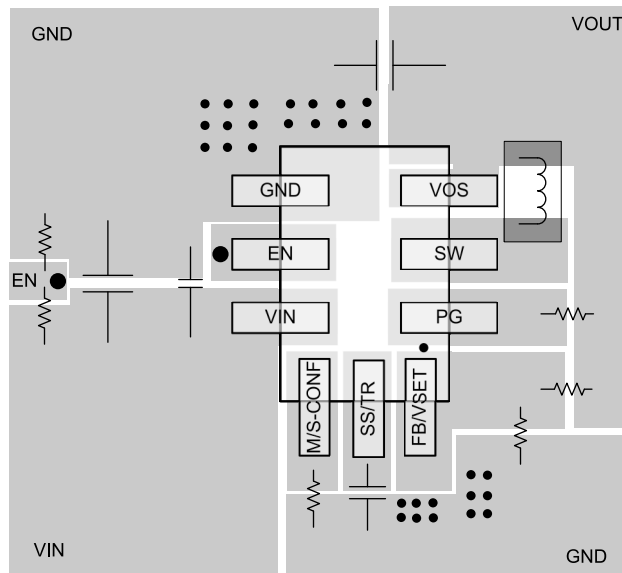
Sensitive nodes like FB and VOS need to be connected with short wires and not nearby high dv/dt signals (for example, SW). As they carry information about the output voltage, they must be connected as close as possible to the actual output voltage (at the output capacitor). The capacitor on the SS/TR pin as well as the FB resistors, R1 and R2, must be kept close to the IC and connected directly to those pins and the system ground plane. The same applies to the VSET resistor if VSET is used to scale the output voltage.

The package uses the pins for power dissipation. Thermal vias on the VIN and GND pins help to spread the heat through the PCB.

In case any of the digital inputs EN and MODE/S-CONF must be tied to the input supply voltage at VIN, the connection must be made directly at the input capacitor as indicated in the schematics.

The recommended layout is implemented on the EVM and shown in the [TPS6290x-Q1 Step-Down Converter Evaluation Module](#) user's guide.

## 9.6.2 Layout Example



9-87. Layout

## 9.6.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

The basic approaches for enhancing thermal performance are:

- Improving the power dissipation capability of the PCB design, for example, increasing copper thickness, thermal vias, number of layers
- Introducing airflow in the system

For more details on how to use the thermal parameters, see the [Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs](#) and [Semiconductor and IC Package Thermal Metrics](#) application reports.

The TPS62993-Q1 is designed for a maximum operating junction temperature ( $T_J$ ) of 165°C. Therefore, the maximum output power is limited by the power losses that can be dissipated over the actual thermal resistance, given by the package and the surrounding PCB structures. If the thermal resistance of the package is given, the size of the surrounding copper area and a proper thermal connection of the IC can reduce the thermal resistance. To get an improved thermal behavior, TI recommends to use top layer metal to connect the device with wide and thick metal lines. Internal ground layers can connect to vias directly under the IC for improved thermal performance.

If short circuit or overload conditions are present, the device is protected by limiting internal power dissipation.

The device is qualified for long term qualification with 165°C junction temperature. For more details about the derating and life time of the HotRod™ package, see the [Derating and Lifetime Calculations for FCOL Packages HotRod and FC-SOT](#) application note.



## 10 Device and Documentation Support

### 10.1 Device Support

#### 10.1.1 サード・パーティ製品に関する免責事項

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#### 10.1.2 Development Support

##### 10.1.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS62993-Q1 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH](http://www.ti.com/WEBENCH).

### 10.2 Documentation Support

#### 10.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Derating and Lifetime Calculations for FCOL Packages HotRod and FC-SOT](#) application note
- Texas Instruments, [Semiconductor and IC Package Thermal Metrics](#) application report
- Texas Instruments, [Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs](#) application report
- Texas Instruments, [TPS6290x-Q1 Step-Down Converter Evaluation Module](#) user's guide
- Texas Instruments, [Using the TPS629210 in an Inverting Buck-Boost Topology](#) application report
- Texas Instruments, [Description Compensating the Current Mode Boost Control Loop](#) application report

### 10.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](http://ti.com) のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 10.4 サポート・リソース

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

## 10.7 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number           | Status<br>(1) | Material type<br>(2) | Package   Pins    | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|---------------------------------|---------------|----------------------|-------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS62993QRYTRQ1</a> | Active        | Production           | VQFN-HR (RYT)   9 | 3000   LARGE T&R      | ROHS Exempt | SN                                   | Level-2-260C-1 YEAR               | -40 to 165   | TS93                |
| TPS62993QRYTRQ1.A               | Active        | Production           | VQFN-HR (RYT)   9 | 3000   LARGE T&R      | ROHS Exempt | SN                                   | Level-2-260C-1 YEAR               | -40 to 165   | TS93                |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

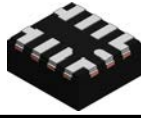
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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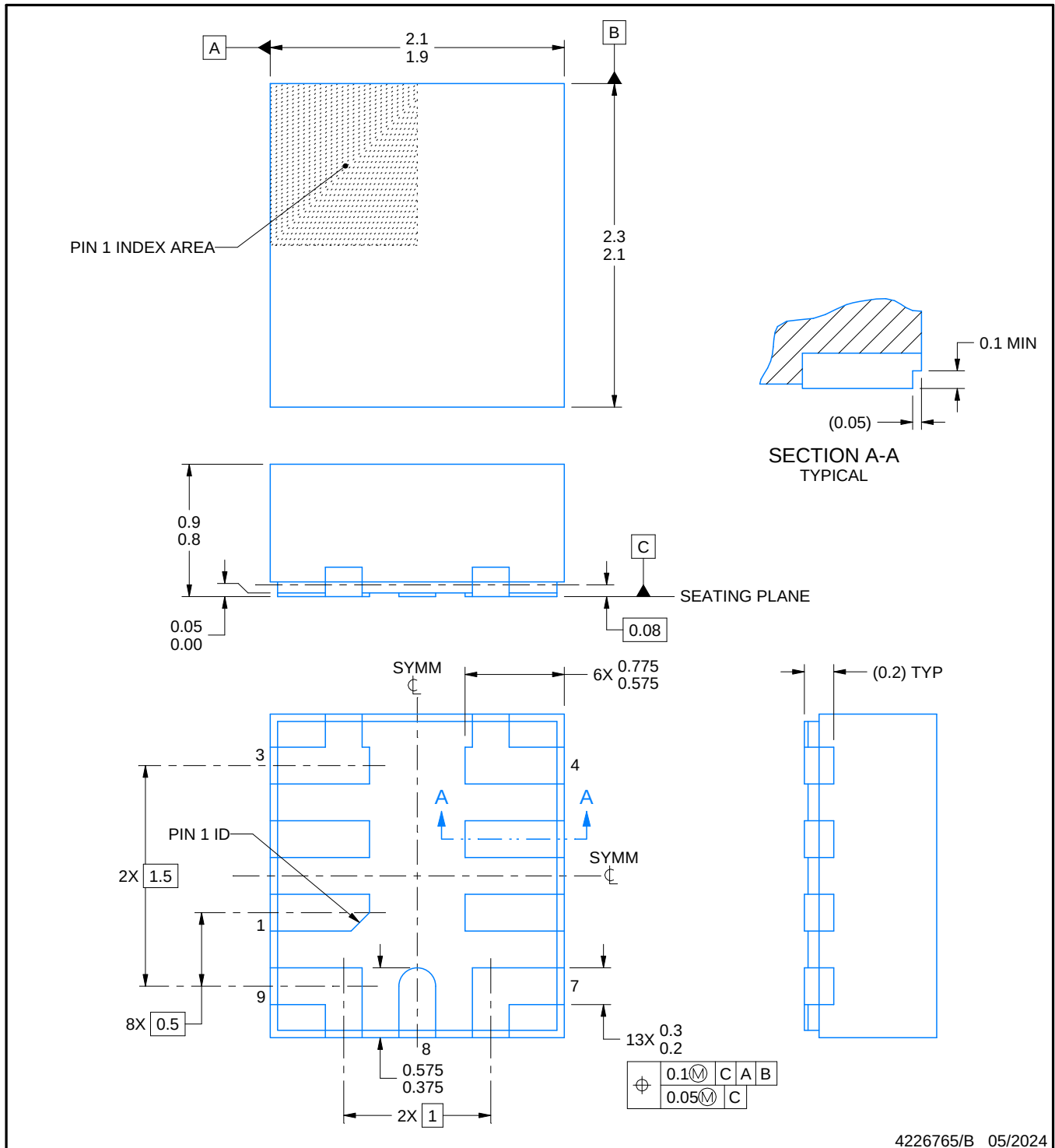
**RYT0009A**



# PACKAGE OUTLINE

**VQFN-HR - 0.9 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



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## NOTES:

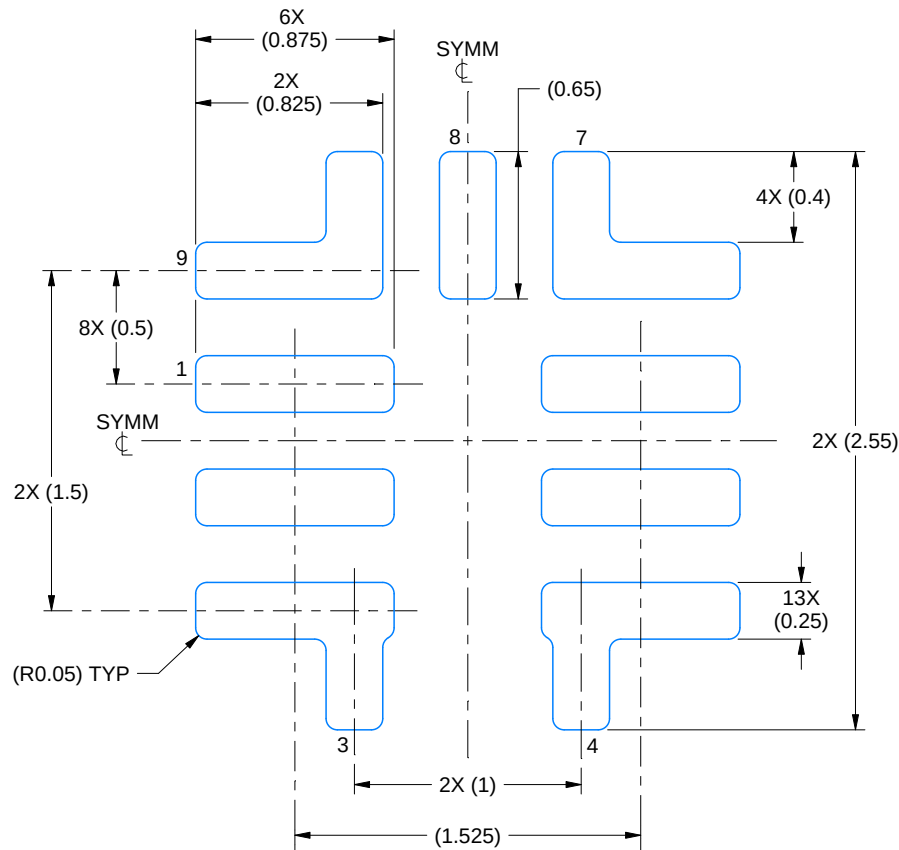
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

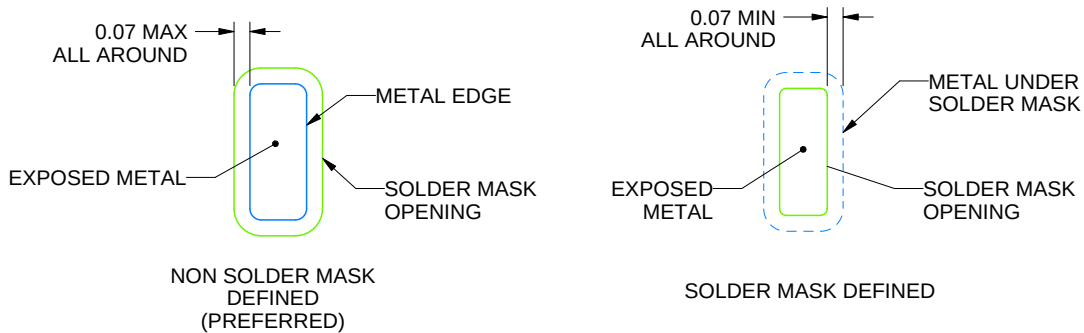
RYT0009A

VQFN-HR - 0.9 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 30X



SOLDER MASK DETAILS

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NOTES: (continued)

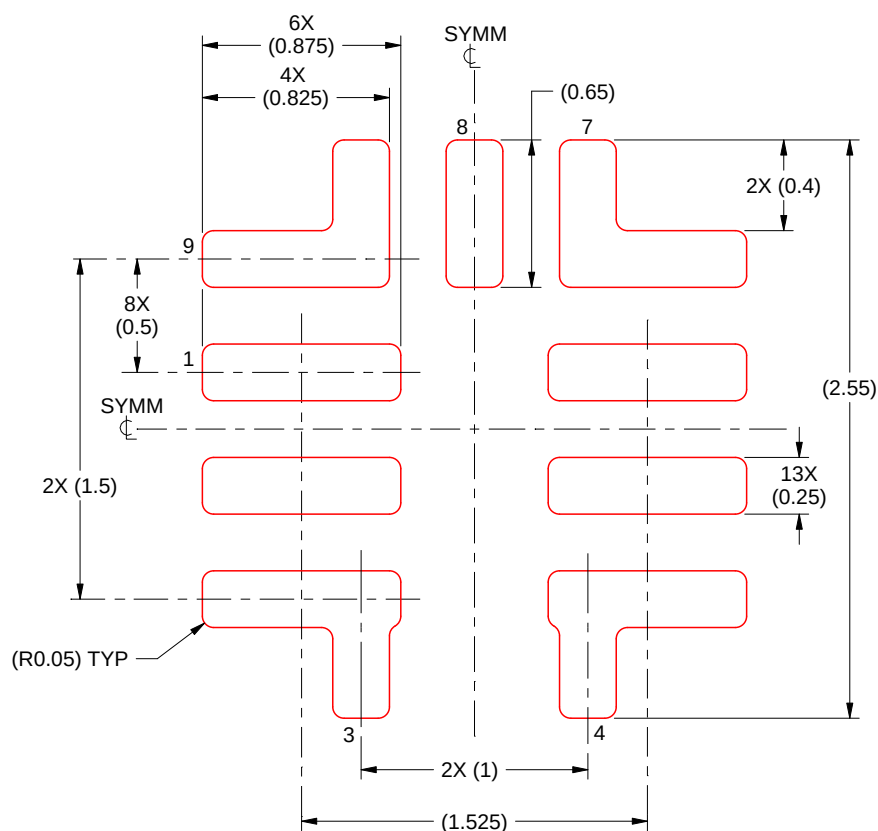
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).

# EXAMPLE STENCIL DESIGN

RYT0009A

VQFN-HR - 0.9 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 MM THICK STENCIL  
SCALE: 30X

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NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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最終更新日：2025 年 10 月